### Freescale Semiconductor

Advance Information

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## **MKW24D512V**



# MKW24D512V

Also covers MKW22D512V and MKW21D256V

Package Information Plastic Package 8x8 56-pin LGA Case 2234-01

#### **Ordering Information**

| Device              | Program<br>flash | System<br>RAM | Package |
|---------------------|------------------|---------------|---------|
| MKW24D512V<br>(USB) | 512 K            | 64 K          | 8x8 LGA |
| MKW22D512V<br>(USB) | 512 K            | 64 K          | 8x8 LGA |
| MKW21D256V          | 256 K            | 32 K          | 8x8 LGA |

### 1 Introduction

The MKW2xDxxxV devices consists of two separate ICs: a 2.4 GHz transceiver and a microcontroller. The MCU is done in the 90 nm thin film storage (TFS) process, is built from the Kinetis platform and is part of the Kinetis portfolio. The transceiver is built using a 180 nm process.

The primary target for the MKW2xDxxxV portfolio is to meet the higher performance requirements of ZigBee Pro and ZigBee IP based applications, especially Smart Energy and Commercial Building Automation. This product is a cost-effective solution that matches or exceeds competitive solutions.

The following content describes the MKW2xDxxxV.

The MKW2xDxxxV portfolio consist of a system on chip for the IEEE® 802.15.4 standard that incorporates a complete, low power, 2.4 GHz 802.15.4 compliant radio frequency transceiver and a Kinetis family low power, mixed-signal ARM® eCortex<sup>TM</sup>- M4 MCU, with a functional set of MCU peripherals integrated into a single package.

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#### **Ordering information** 1.1

| Device           | Program<br>flash | System RAM |
|------------------|------------------|------------|
| MKW24D512V (USB) | 512 K            | 64 K       |
| MKW22D512V (USB) | 512 K            | 64 K       |
| MKW21D256V       | 256 K            | 32 K       |

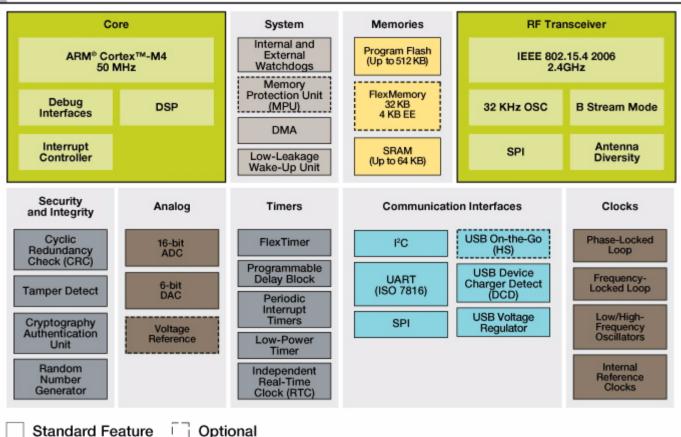
Table 1. Orderable parts details

#### **Features** 2

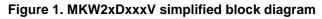
This section provides a simplified block diagram and highlights MKW2xDxxxV features.

#### **Block diagram** 2.1

Figure 1 shows a simplified block diagram of the MKW2xDxxxV, which is an IEEE®802.15.4 standard compatible transceiver.







### 2.2 Radio features

- 2.4 GHz frequency band of operation
- 250 kbps data rate with O-QPSK modulation in 5.0 MHz channels with direct sequence spread-spectrum (DSSS) encode and decode
- Operates on one of 16 selectable channels per IEEE 802.15.4 specification
- Programmable output power
- Supports 2.36 to 2.4 GHz Medical Band (MBAN) frequencies with same modulation as IEEE 802.15.4
- Small RF footprint
  - Differential input/output port used with external balun
  - Integrated transmit/receive switch
  - Supports single ended and diversity antenna options
  - Low external component count
  - Supports external PA and LNA
- Hardware acceleration for IEEE® 802.15.4 2006 packet processing
  - Random number generator
  - Support for dual PAN mode
- 32 MHz crystal reference oscillator with on board trim capability to supplement external load capacitors
- Programmable frequency clock output (CLK\_OUT)
- Bit stream mode (BSM) to monitor packet data with synchronization clock
- Advanced Security Module with support for AES encryption
- GPIO for Antenna Diversity control
- Clocks
  - 32 MHz crystal oscillator
  - Internal 1 kHz low power oscillator
  - DC to 32 MHz external square wave input clock

### 2.3 Microcontroller features

In addition all MKW2xDxxxV devices contain the below microcontroller features:

- Core:
  - ARM Cortex-M4 Core delivering 1.25 DMIPS/MHz with DSP instructions (floating-point unit available on certain Kinetis families)
  - 16-channel DMA for peripheral and memory servicing with minimal CPU intervention
- Reliability, Safety and Security:
  - Hardware cyclic redundancy check engine for validating memory contents/communication data and increased system reliability
  - Independent-clocked COP for protection against code runaway in fail-safe applications

- External watchdog monitor
- Analog tamper detects (voltage, temperature, and clock)
- External tamper detect
- 256-bit secure storage (asynchronously erased on tamper detect)
- Ultra-low power:
  - 10 low power operating modes for optimizing peripheral activity and wake-up times for extended battery life.
  - Low-leakage wake-up unit, low power timer, and low power RTC for additional low power flexibility
  - Industry-leading fast wake-up times
- Memory:
  - FlexMemory with up to 512 KB FlexNVM and up to 4 KB FlexRAM. FlexNVM can be partitioned to support additional program flash memory (ex. bootloader), data flash (ex. storage for large tables), or EEPROM backup. FlexRAM supports
  - EEPROM byte-write/byte-erase operations and dictates the maximum EEPROM size.
  - EEPROM endurance capable of exceeding 10 million cycles
  - EEPROM erase/write times an order of magnitude faster than traditional EEPROM
- Connectivity and Communications:
  - UART, I2C and DSPI
- Mixed-signal analog:
  - Fast, high precision 16-bit ADC. Powerful signal conditioning, conversion and analysis capability with reduced system cost
- Timing and Control:
  - Powerful FlexTimers which support general purpose, PWM, and motor control functions
  - Programmable Interrupt Timer for RTOS task scheduler time base or trigger source for ADC conversion and programmable delay block
- System:
  - Wide operating voltage range from 1.8 V to 3.6 V with flash programmable down to 1.8 V with fully functional flash and analog peripherals
  - Ambient operating temperature ranges from  $-40^{\circ}$ C to  $105^{\circ}$ C

MKW2xDxxxV devices are supported by a market-leading enablement bundle from Freescale and numerous ARM 3rd party ecosystem partners.

Common features among the MKW2xDxxxV family:

- Operating characteristics
  - Voltage range 1.8 V 3.6 V
  - Flash memory programming down to 1.8 V
  - Temperature range (TA) –40 to 105°C
  - Flexible modes of operation

- Core features
  - Next generation 32-bit ARM Cortex-M4 core
  - Supports DSP instructions
  - Nested vectored interrupt controller (NVIC)
  - Asynchronous wake-up interrupt controller (AWIC)
  - Debug and trace capability
    - 2-pin serial wire debug (SWD)
    - IEEE 1149.1 Joint Test Action Group (JTAG)
    - IEEE 1149.7 compact JTAG (cJTAG)
    - Trace port interface unit (TPIU)
    - Flash patch and breakpoint (FPB)
    - Data watchpoint and trace (DWT)
    - Instrumentation trace macrocell (ITM)
    - Enhanced Trace Macrocell (ETM)
- System and power management
  - Software and hardware watchdog with external monitor pin
  - DMA controller with 16 channels
  - Low-leakage wake-up unit (LLWU)
  - Power management controller with 10 different power modes
  - Non-maskable interrupt (NMI)
  - 128-bit unique identification (ID) number per chip
- Clocks
  - Multi-purpose clock generator
    - PLL and FLL operation
    - Internal reference clocks (32 kHz or 2 MHz)
  - Three separate crystal oscillators
    - 3 MHz to 32 MHz crystal oscillator for MCU
    - 32 kHz to 40 kHz crystal oscillator for MCU or RTC
    - 32 MHz crystal oscillator for Radio
  - Internal 1 kHz low power oscillator
  - DC to 50 MHz external square wave input clock
- Memories and Memory Interfaces
  - FlexMemory consisting of FlexNVM (non-volatile flash memory that can execute program code, store data, or backup EEPROM data) or FlexRAM (RAM memory that can be used as traditional RAM or as high-endurance EEPROM storage, and also accelerates flash programming)
  - Flash security and protection features
  - Serial flash programming interface (EzPort)

- Security and integrity
  - Cyclic redundancy check (CRC)
  - Tamper detect
  - Hardware encryption
  - AES128 Hardware encryption
- Analog
  - 16-bit SAR ADC
  - High-speed Analog comparator (CMP) with 6-bit DAC
- Timers
  - Up to 12 channels; 7 channels support external connections; 5 channels are internal only
  - Carrier modulator timer (CMT)
  - Programmable delay block (PDB)
  - 1x4ch programmable interrupt timer (PIT)
  - Low-power timer (LPT)
- Communications
  - SPI
  - I2C with SMBUS support
  - UART (w/ ISO7816, IrDA and hardware flow control)
- Human-machine interface
  - GPIO with pin interrupt support, DMA request capability, digital glitch filter, and other pin control options

### 3 Transceiver description

### 3.1 Key specifications

MKW2xDxxxV meets or exceeds all IEEE 802.15.4 performance specifications applicable to 2.4 GHz ISM and MBAN (Medical Band Area Network) bands. Key specifications for MKW2xDxxxV are:

- ISM band:
  - RF operating frequency: 2405 MHz to 2480 MHz (center frequency range)
  - ISM Channel numbering: Fc = 2405 + 5 (k 11) in MHz, k = 11, 12, ..., 26.
- MBAN band:
  - RF operating frequency: 2360 MHz to 2400 MHz (center frequency range)
  - MBANS channel page 9 is (2360 MHz–2390 MHz band)
  - --- Fc = 2363.0 + 1.0 \* k in MHz for k = 0.....26
  - MBANS channel page 10 is (2390 MHz–2400 MHz band)
  - Fc = 2390.0 + 1.0 \* k in MHz for k = 0.....8
- IEEE 802.15.4 Standard 2.4 GHz modulation scheme
  - Chip rate: 2000 kbps

- Data rate: 250 kbps
- Symbol rate: 62.5 kbps
- Modulation: OQPSK
- Receiver sensitivity: -102 dBm, typical (@1% PER for 20 byte payload packet)
- Differential bidirectional RF input/output port with integrated transmit/receive switch
- Programmable output power from -30 dBm to +10 dBm.

### 3.2 RF interface and usage

The MKW2xDxxxV RF output ports are bidirectional (diplexed between receive/transmit modes) and differential enabling interfaces with numerous off-chip devices such as a balun. When using a balun, this device provides an interface to directly connect between a single-ended antenna with MKW2xDxxxV RF ports. In addition, MKW2xDxxxV provides four output driver ports that can have both drive strength and slew rate configured to control external peripheral devices. These signals designated ANT\_A, ANT\_B, RX\_SWITCH, and TX\_SWITCH when enabled are switched via an internal hardware state machine. These ports provide control features for peripheral devices such as:

- Antenna diversity modules
- External PAs
- External LNAs
- T/R switched

### 3.2.1 Clock output feature

The CLK\_OUT digital output can be enabled to drive the system clock to the MCU. This provides a highly accurate clock source based on the transceiver reference oscillator. The clock is programmable over a wide range of frequencies divided down from the reference 32 MHz (see Table 3). The CLK\_OUT pin will be enabled upon POR. The frequency CLK\_OUT will be determined by the state of the GPIO5/BOPT pin. If this pin is low upon POR, then the frequency will be 4 MHz (32 MHz/8). If this pin is high upon POR (upon POR GPIO5 has a pullup resistor) then the frequency will be 32.78689 kHz (32 MHz/976).

### 3.3 Transceiver functions

### 3.3.1 Receive path

The receive path has the functionality to operate in run state or operate in a low power run state (LPRS) that can be considered as a partial power down mode. The radio receiver path is based upon a near zero IF (NZIF) architecture incorporating front end amplification, one(1) mixed signal down conversion to IF that is programmably filtered, demodulated and digitally processed. The RF front end (FE) input port is differential that shares the same off chip matching network with the transmit path.

### 3.3.2 Transmit path

MKW2xDxxxV transmits OQPSK modulation having power and channel selection adjustment per user application. After the channel of operation is determined, coarse and fine tuning is executed within the Frac-N PLL to engage signal lock. After signal lock is established, the modulated buffered signal is then routed to a multi-stage amplifier for transmission. The differential signals at the output of the PA (RFOUTP, RFOUTN) are converted as single ended (SE) signals with off chip components as required.

# 3.3.3 Clear channel assessment (CCA), energy detection (ED), and link quality indicator (LQI)

MKW2xDxxxV supports three clear channel assessment (CCA) modes of operation to include energy detection (ED) and link quality indicator (LQI). Functionality for each of these modes is provided in the sections that follow.

### 3.3.3.1 CCA mode 1

CCA mode 1 has two functions:

- To estimate the energy in the received baseband signal. This energy is estimated based on receiver signal strength indicator (RSSI).
- To determine whether the energy is greater than a threshold.

The estimate of the energy can also be used as the Link Quality metric. In CCA Mode 1, MKW2xDxxxV warms up from Idle to Receive mode where RSSI (Receiver Signal Strength Indicator) averaging takes place right after 170µs of receiver warm-up.

### 3.3.3.2 CCA mode 2

CCA mode 2 detects whether there is any 802.15.4 signal transmitting at the frequency band that an 802.15.4 transmitter intends to transmit. From the definition of CCA mode 2 in the 802.15.4 standard, the requirement is to detect an 802.15.4 complied signal. Whether the detected energy is strong or not is not important for CCA mode 2.

#### 3.3.3.3 CCA mode 3

CCA mode 3 as defined by 802.15.4 standard is implemented using a logical combination of CCA mode 1 and CCA mode 2. Specifically, CCA mode 3 operates in one of two operating modes:

- CCA mode 3 is asserted if both CCA mode 1 and CCA mode 2 are asserted.
- CCA mode 3 is asserted if either CCA mode 1 or CCA mode 2 is asserted.

This mode setting is available through a programmable register.

### 3.3.3.4 Energy detection (ED)

Energy detection (ED) is based on receiver signal strength indicator (RSSI) and correlator output for the 802.15.4 standard. energy detect (ED) is an average value of signal strength. The magnitude from this measurement is calculated from the digital RSSI value that is averaged over an 128 µs duration.

### 3.3.3.5 Link quality indicator (LQI)

Link quality indicator (LQI), is based on receiver signal strength indicator (RSSI) or correlator output for the 802.15.4 standard. In this mode, RSSI measurement is done during normal packet reception. LQI computations for MKW2xDxxxV are based on either digital RSSI or correlator peak values. This setting is executed through a register bit where the final LQI value is available 64 µs after preamble is detected. If a continuous update of LQI based on RSSI throughout the packet is desired, it can be read in a separate 8-bit register by enabling continuous update in a register bit.

### 3.3.4 Packet processor

The MKW2xDxxxV packet processor performs sophisticated hardware filtering of the incoming received packet, to determine whether the packet is both PHY- and MAC-compliant, whether the packet is addressed to this device, and if the device is a PAN coordinator, whether a message is pending for the sending device. The packet processor greatly reduces the packet filtering burden on software, allowing software to tend to higher-layer tasks with a lower latency and smaller software footprint.

#### 3.3.4.1 Features

- Aggressive packet filtering to enable long, uninterrupted MCU sleep periods
- Fully compliant with both 2003 and 2006 versions of the 802.15.4 wireless standard
- Supports all frame types, including reserved types
- Supports all valid 802.15.4 frame lengths
- Enables auto-Tx acknowledge frames (no MCU intervention) by parsing of frame control field and sequence number
- Supports all source and destination address modes, and also PAN ID compression
- Supports broadcast address for PAN ID and short address mode
- Supports "promiscuous" mode, to receive all packets regardless of address- and rules-checking
- Allows frame type-specific filtering (e.g., reject all but beacon frames)
- Supports SLOTTED and non-SLOTTED modes
- Includes special filtering rules for PAN coordinator devices
- Enables minimum-turnaround Tx-acknowledge frames for data-polling requests by automatically determining message-pending status
- Assists MCU in locating pending messages in its indirect queue for data-polling end devices
- Makes available to MCU detailed status of frames that fail address- or rules-checking.
- Supports Dual PAN mode, allowing the device to exist on 2 PAN's simultaneously
- Supports 2 IEEE addresses for the device

• Supports active promiscuous mode

### 3.3.5 Packet buffering

The packet buffer is a 128-byte random access memory (RAM) dedicated to the storage of 802.15.4 packet contents for both TX and RX sequences. For TX sequences, software stores the contents of the packet buffer starting with the frame length byte at packet buffer address 0, followed by the packet contents at the subsequent packet buffer addresses. For RX sequences the incoming packet's frame length is stored in a register, external to the packet buffer. Software will read this register to determine the number of bytes of packet buffer to read. This facilitates DMA transfer through the SPI. For receive packets, an LQI byte is stored at the byte immediately following the last byte of the packet (frame length +1). Usage of the packet buffer for RX and TX sequences is on a time-shared basis; receive packet data will overwrite the contents of the packet buffer. Software can inhibit receive-packet overwriting, but will not inhibit TX content loading of the packet buffer via the SPI.

#### 3.3.5.1 Features

- 128 byte buffer stores maximum length 802.15.4 packets
- Same buffer serves both TX and RX sequences
- The entire Packet Buffer can be uploaded or downloaded in a single SPI burst.
- Automatic address auto-incrementing for burst accesses
- Single-byte access mode supported.
- Entire packet buffer can be accessed in hibernate mode
- Under-run error interrupt supported

### 3.4 Dual PAN ID

In the past, radio transceivers designed for 802.15.4 and ZigBee applications allowed a device to associate to one and only one PAN (Personal Area Network) at any given time. MKW2xDxxxV represents a high-performance SoC that includes hardware support for a device to reside in two networks simultaneously. In optional Dual PAN mode, the device alternates between the two (2) PANs under hardware or software control. Hardware support for Dual PAN operation consists of two (2) sets of PAN and IEEE addresses for the device, two (2) different channels (one for each PAN), a programmable timer to automatically switch PANs (including on-the-fly channel changing) without software intervention. There are control bits to configure and enable Dual PAN mode and read only bits to monitor status in Dual PAN mode. A device can be configured to be a PAN coordinator on either network, both networks, or neither.

For the purpose of defining PAN in the content of Dual PAN mode, two (2) sets of network parameters are maintained, PAN0 and PAN1. PAN0 and PAN1 will be used to refer to the two (2) PANs where each parameter set uniquely identifies a PAN for Dual PAN mode. These parameters are described in Table 2.

| PAN0                             | PAN1                             |
|----------------------------------|----------------------------------|
| Channel0 (PHY_INT0, PHY_FRAC0)   | Channel1 (PHY_INT1, PHY_FRAC1)   |
| MacPANID0 (16-bit register)      | MacPANID1 (16-bit register)      |
| MacShortAddrs0 (16-bit register) | MacShortAddrs1 (16-bit register) |
| MacLongAddrs0 (64-bit registers) | MacLongAddrs1 (64-bit registers) |
| PANCORDNTR0 (1-bit register)     | PANCORDNTR1 (1-bit register)     |

#### Table 2. PAN0 and PAN1 descriptions

During device initialization if Dual PAN mode is used, software will program both parameter sets to configure the hardware for operation on two (2) networks.

## 4 System and power management

The MKW2xDxxxV is a low power device that also supports extensive system control and power management modes to maximize battery life and provide system protection.

### 4.1 Modes of operation

The transceiver modes of operation include:

- Idle mode
- Doze mode
- Low power (LP) / hibernate mode
- Reset / powerdown mode
- Run mode

### 4.2 Power management

The MKW2xDxxxV power management is controlled through programming the modes of operation. Different modes allow for different levels of power-down and RUN operation. For the receiver, programmable power modes available are:

- Receiver modes of operation:
  - RX preamble search
  - RX Preamble search sniff
  - X FAD Preamble search
  - RX packet decoding
- The RF section of the radio only powered-up as required to do a TX, RX, or CCA/ED operation.

## 5 Radio Peripherals

The MKW2xDxxxV provides a set of I/O pins useful for suppling a system clock to the MCU, controlling external RF modules/circuitry, and GPIO. In addition, there is a special option for streaming the digital packet data for external monitoring (BSM).

### 5.1 Clock output (CLK\_OUT)

MKW2xDxxxV integrates a programmable clock to source numerous frequencies for connection with various MCUs. Package pin 39 can be used to provide this clock source as required allowing the user to make adjustments per their application requirement.

The transceiver CLK\_OUT pin is internally connected to the MCU EXTAL pin so that no external connection is needed to drive the MCU clock.

Care must be taken that the clock output signal does not "talk" or interfere with the reference oscillator or the radio. Additional functionality this feature supports is:

- 3 clock domains (XTAL, SCLK, SDM\_CK).
- Built in synchronization at all clock domain crossings.
- Aggressive clock gating in the XTAL domain to minimize dynamic current consumption based on the power mode selected.
- XTAL domain can be completely gated off (hibernate mode)
- SPI communication allowed in hibernate
- Single-clock domain in scan mode

| CLK_OUT_DIV [2:0] | CLK_OUT frequency | Comments                |
|-------------------|-------------------|-------------------------|
| 0                 | 32 MHz            |                         |
| 1                 | 16 MHz            |                         |
| 2                 | 8 MHz             |                         |
| 3                 | 4 MHz             | DEFAULT if GPIO5/BOPT=0 |
| 4                 | 2 MHz             |                         |
| 5                 | 1 MHz             |                         |
| 6                 | 62.5 kHz          |                         |
| 7                 | 32.786 kHz        | DEFAULT if GPIO5/BOPT=1 |

#### Table 3. CLK\_OUT table

There is an enable and disable bit for CLK\_OUT. When disabling, the clock output will optionally continue to run for 128 clock cycles after disablement. There will also be one (1) bit available to adjust the CLK\_OUT I/O pad drive strength.

### 5.2 Bit streaming mode (BSM)

Another peripheral option is bit streaming mode that when activated allows all 802.15.4 packet data, received or transmitted, to be serialized and shifted out to external hardware for further processing. A simple development system can be crafted to consume the BSM outputs and generate packet trace data for

all 802.15.4 traffic appearing on a network within the range of the MKW2xDxxxV device allowing for PAN-level monitoring and debugging.

BSM uses a simple synchronous 3-wire interface consisting of BSM\_CLK, BSM\_DATA, and BSM\_FRAME outputs. Packet data is shifted out serially at the 802.15.4 bit rate (250 kHz). Signaling is provided on BSM\_FRAME to indicate start-of-packet and end-of-packet and to discriminate between TX and RX packet types. BSM\_DATA and BSM\_FRAME are synchronous to BSM\_CLK. BSM\_DATA and BSM\_FRAME are shifted out on the falling BSM\_CLK and intended to be captured on rising BSM\_CLK.

A single shift register control bit activates or deactivates BSM. Aside from controlling this bit, BSM requires no software support while the mode is engaged. BSM outputs are multiplexed with GPIO, so that the pins are available for general-purpose use when BSM is disabled. BSM does not interfere with packet processing or transmit data handling in any way, it is merely a monitoring tool. BSM when engaged will not measurably increase current consumption because the hardware (including the external I/O) operates at the 250 kHz rate.

### 5.3 General-purpose input output (GPIO)

MKW2xDxxxV embedded transceiver supports up to 8 GPIO pins where all I/O pins will have the same supply voltage, which depending on the battery can vary from 1.8 V up to 3.6 V. Not all 8 are available on the MKW2xDxxxV. When a die pin is configured as a general-purpose output or for peripheral use, there will be specific settings required per use case. Pin configuration will be executed by software to adjust input/output direction and drive strength, capability. When a die pin is configured as a general-purpose input or for peripheral use, software (see Table 4) can enable a pull-up or pull-down device. Immediately after reset, all pins are configured as high-impedance general-purpose inputs with "internal pull-up or pull-down devices enabled".

Features for these pins include:

- Programmable output drive strength
- Programmable output slew rate
- Hi-Z mode
- Programmable as outputs or inputs (default)
- Pins shared with BSM mode outputs

| Din function configuration                 | Details                         |      | Tolerance | Linita |       |
|--|---------------------------------|------|-----------|--------|-------|
| Pin function configuration                 | Details                         | Min. | Тур.      | Max.   | Units |
| I/O buffer full drive mode <sup>1</sup>    | Source or sink                  | _    | ±10       | —      | mA    |
| I/O buffer partial drive mode <sup>2</sup> | Source or sink                  | —    | ±2        | —      | mA    |
| I/O buffer high impedance <sup>3</sup>     | Off state                       | —    | —         | 10     | nA    |
| No slew, full drive                        | Rise and fall time <sup>4</sup> | 2    | 4         | 6      | ns    |
| No slew, partial drive                     | Rise and fall time              | 2    | 4         | 6      | ns    |
| Slew, full drive                           | Rise and fall time              | 6    | 12        | 24     | ns    |
| Slew, partial drive                        | Rise and fall time              | 6    | 12        | 24     | ns    |
| Propagation delay <sup>5</sup> , no slew   | Full drive <sup>6</sup>         | _    | —         | 11     | ns    |
| Propagation delay, no slew                 | Partial drive <sup>7</sup>      | —    | —         | 11     | ns    |
| Propagation delay, slew                    | Full drive                      | —    | —         | 50     | ns    |
| Propagation delay, slew                    | Partial drive                   | —    | -         | 50     | ns    |

#### Table 4. Pin configuration summary

For this drive condition, the output voltage will not deviate more than 0.5 V from the rail reference VOH or VOL.

<sup>2</sup> For this drive condition, the output voltage will not deviate more than 0.5 V from the rail reference VOH or VOL.

<sup>3</sup> Leakage current applies for the full range of possible input voltage conditions.

<sup>4</sup> Rise and fall time values in reference to 20% and 80%

<sup>5</sup> Propagation Delay measured from/to 50% voltage point.

<sup>6</sup> Full drive values provided are in reference to a 75 pF load.

<sup>7</sup> Partial drive values provided are in reference to a 15 pF load.

### 5.3.1 Serial peripheral interface (SPI)

MKW2xDxxxV's SPI interface allows an MCU to communicate with MKW2xDxxxV's register set and packet buffer. The SPI is a slave-only interface; the MCU must drive R\_SSEL\_B, R\_SCLK and R\_MOSI. Write and read access to both direct and indirect registers is supported, and transfer length can be single-byte, or bursts of unlimited length. Write and read access to the Packet buffer can also be single-byte, or a burst mode of unlimited length. The SPI interface is asynchronous to the rest of the IC. No relationship between R\_SCLK and MKW2xDxxxV's internal oscillator is assumed. And no relationship between R\_SCLK and the CLK\_OUT pin is assumed. All synchronization of the SPI interface to the IC takes place inside the SPI module. SPI synchronization takes place in both directions: SPI-to-IC (register writes), and IC-to-SPI (register reads). The SPI is capable of operation in all power modes, except Reset. Operation in hibernate mode allows most MKW2xDxxxV registers and the complete packet buffer to be accessed in the lowest-power operating state enabling minimal power consumption, especially during the register-initialization phase of the IC. The SPI design features a compact, single-byte control word, reducing SPI access latency to a minimum. Most SPI access types require only a single-byte control word, with the address embedded in the control word. During control word transfer (the first byte of any SPI access), the contents of the IRQSTS1 register (MKW2xDxxxV's highest-priority status register) are

always shifted out, so that the MCU gets access to IRQSTS1, with the minimum possible latency, on every SPI access.

#### 5.3.1.1 Features

- 4-wire industry standard interface, supported by all MCUs
- SPI R\_SCLK maximum frequency 16 MHz (for SPI write accesses).
- SPI R\_SCLK maximum frequency 9 MHz (for SPI read accesses).
- Write and read access to all Coconino registers (direct and indirect)
- Write and read access to packet buffer
- SPI accesses can be single-byte or burst.
- Automatic address auto-incrementing for burst accesses
- The entire packet buffer can be uploaded or downloaded in a single SPI burst.
- Entire packet buffer, and most registers, can be accessed in hibernate mode
- Built-in synchronization inside the SPI module to/from the rest of the IC.
- R\_MISO can be tristated when SPI inactive, enabling multi-slave configurations

### 5.3.2 Antenna diversity

To improve the reliability of RF connectivity to long range applications, the antenna diversity feature is supported without using the MCU through use of four dedicated control pins (package pins 44, 45, 46, and 47) by direct register antenna selection. The digital regulator supplies bias to analog switches that can be programmed to sink and source current or operate in a high impedance mode.

Fast antenna diversity (FAD) mode supports this radio feature and, when enabled, will allow the choice of selection between two antennas during the preamble phase. By continually monitoring the received signal, the FAD block will select the first antenna on which the received signal has a correlation factor above a predefined progammable threshold. The FAD accomplishes the antenna selection by sequentially switching between the two antennas testing for the presence of a suitably strong signals/symbols where the first antenna to reach this condition is then selected for the received of the packet.

The first antenna is monitored for a period equal to 1 symbol,  $t_s = 16 \mu s$ , then antenna monitoring is switched to the second antenna,  $t_a = 8 \mu s$ . The period  $t_a$  is required to allow for the external module control circuitry to turn on/off to select the antenna.  $t_s + t_a = 24 \mu s$  that will allow enough time to test both antennas within the first 4 preamble symbols,  $t_{fad} = 3 x t_a + 2 x t_s = 56 \mu s$ , thus  $t_{fad} < 4 x t_s < 64 \mu s$ . Operationally, FAD will continue to switch between the two antennas until one is found that has a sufficiently strong detected signal. FAD's operation covers less than four s0 symbols before the antenna that is selected allowing the symbol demodulator to detect at least four s0 symbols before declaring "Preamble Detect".

## 6 MKW2xDxxxV operating modes

The radio has these 6 operating modes:

- Reset / power down
- Low power (LP) / hibernate

- Doze (low power with reference oscillator active)
- Idle
- Receive
- Transmit

Table 5 lists and describes these modes.

#### Table 5. Radio mode definitions and transition times

| Mode                     | Definition   | Current consumption <sup>1</sup> | Transition time to or from idle |
|--------------------------|--|----------------------------------|---------------------------------|
| Reset /<br>powerdown     | All IC functions off, leakage only. RST asserted.                              | < 30 nA                          | TBD                             |
| Low power /<br>hibernate | Crystal reference oscillator off. (SPI is functional.)                         | < 1 µA                           | TBD                             |
| Doze                     | Crystal reference oscillator on but CLK_OUT output available only if selected. | 600 μA<br>(no clockout)          | TBD                             |
| Idle                     | Crystal reference oscillator on with CLK_OUT output available.                 | 700 μA<br>(no clockout)          | TBD                             |
| Receive                  | Crystal reference oscillator on. Receiver on.                                  | 15 mA <sup>2</sup>               | TBD                             |
| Transmit                 | Crystal reference oscillator on. Transmitter on.                               | 15 mA <sup>3</sup>               | TBD                             |

<sup>1</sup> Conditions: VBAT and VBAT\_2 = 2.7 V, nominal process @ 25°C

<sup>2</sup> Signal sensitivity = -102 dBm

<sup>3</sup> RF output = 0 dBm

#### The MCU has these radio modes:

#### Table 6. MCU power modes

| Chip mode  | Description   | Core mode | Normal<br>recovery<br>method |
|------------|---|-----------|------------------------------|
| Normal run | Allows maximum performance of chip. Default mode out of reset; on-<br>chip voltage regulator is on. | Run       |                              |

Table continues on the next page ...

| Chip mode  | Description   | Core mode  | Normal<br>recovery<br>method     |  |
|--|---|------------|----------------------------------|--|
| Normal Wait -<br>via WFI   | Allows peripherals to function while the core is in sleep mode,<br>reducing power. NVIC remains sensitive to interrupts; peripherals<br>continue to be clocked.   | Sleep      | Interrupt                        |  |
| Normal Stop -<br>via WFI   | Places chip in static state. Lowest power mode that retains all registers while maintaining LVD protection. NVIC is disabled; AWIC is used to wake up from interrupt; peripheral clocks are stopped.  | Sleep Deep | Interrupt                        |  |
| VLPR (Very<br>Low Power<br>Run)  | On-chip voltage regulator is in a low power mode that supplies only<br>enough power to run the chip at a reduced frequency. Reduced<br>frequency Flash access mode (1 MHz); LVD off; internal oscillator<br>provides a low power 4 MHz source for the core, the bus and the<br>peripheral clocks.   | Run        | Interrupt                        |  |
| VLPW (Very<br>Low Power<br>Wait) -via WFI  | Same as VLPR but with the core in sleep mode to further reduce<br>power; NVIC remains sensitive to interrupts (FCLK = ON). On-chip<br>voltage regulator is in a low power mode that supplies only enough<br>power to run the chip at a reduced frequency.   | Sleep      | Interrupt                        |  |
| VLPS (Very<br>Low Power         Places chip in static state with LVD operation off. Lowest power mode<br>with ADC and pin interrupts functional. Peripheral clocks are stopped,<br>but LPTimer, RTC, CMP, DAC can be used. NVIC is disabled (FCLK =<br>OFF); AWIC is used to wake up from interrupt. On-chip voltage<br>regulator is in a low power mode that supplies only enough power to<br>run the chip at a reduced frequency. All SRAM is operating (content<br>retained and I/O states held). |   | Sleep Deep | Interrupt                        |  |
| LLS (Low<br>Leakage Stop)  | <ul> <li>State retention power mode. Most peripherals are in state retention mode (with clocks stopped), but LLWU, LPTimer, RTC, CMP, DAC can be used. NVIC is disabled; LLWU is used to wake up.</li> <li>NOTE: The LLWU interrupt must not be masked by the interrupt controller to avoid a scenario where the system does not fully exit stop mode on an LLS recovery.</li> <li>All SRAM is operating (content retained and I/O states held).</li> </ul> | Sleep Deep | Wakeup<br>Interrupt <sup>1</sup> |  |
| VLLS3 (Very<br>Low Leakage<br>Stop3)       Most peripherals are disabled (with clocks stopped), but LLWU,<br>LPTimer, RTC, CMP, DAC can be used. NVIC is disabled; LLWU is<br>used to wake up.         SRAM_U and SRAM_L remain powered on (content retained and I/O<br>states held).  |   | Sleep Deep | Wakeup Reset <sup>2</sup>        |  |
| VLLS2 (Very<br>Low Leakage<br>Stop2)   | Most peripherals are disabled (with clocks stopped), but LLWU,<br>LPTimer, RTC, CMP, DAC can be used. NVIC is disabled; LLWU is<br>used to wake up.<br>SRAM_L is powered off. A portion of SRAM_U remains powered on  | Sleep Deep | Wakeup Reset <sup>2</sup>        |  |
| VLLS1 (Very<br>Low Leakage<br>Stop1)   | (content retained and I/O states held).<br>Most peripherals are disabled (with clocks stopped), but LLWU,<br>LPTimer, RTC, CMP, DAC can be used. NVIC is disabled; LLWU is<br>used to wake up.<br>All of SRAM_U and SRAM_L are powered off. The 32-byte system<br>register file and the 32-byte VBAT register file remain powered for   | Sleep Deep | Wakeup Reset <sup>2</sup>        |  |

Table continues on the next page ...

| Chip mode                             | Description   | Core mode  | Normal<br>recovery<br>method |
|---------------------------------------|---|------------|------------------------------|
| VLLS0 (Very<br>Low Leakage<br>Stop 0) | Most peripherals are disabled (with clocks stopped), but LLWU and<br>RTC can be used. NVIC is disabled; LLWU is used to wake up.<br>All of SRAM_U and SRAM_L are powered off. The 32-byte system<br>register file and the 32-byte VBAT register file remain powered for<br>customer-critical data.<br>The POR detect circuit can be optionally powered off. | Sleep Deep | Wakeup Reset <sup>2</sup>    |
| BAT (backup<br>battery only)          | The chip is powered down except for the VBAT supply. The RTC and the 32-byte VBAT register file for customer-critical data remain powered.  | Off        | Power-up<br>Sequence         |

Resumes normal run mode operation by executing the LLWU interrupt service routine.
 Follows the reset flow with the LLWU interrupt flag set for the NVIC.

| MCU Mode         | Radio Mode               | MCU typical current<br>consumption | Radio typical current consumption |
|------------------|--------------------------|------------------------------------|-----------------------------------|
| Stop             | Idle                     | 320 μA                             | 700 μA, typ. (no CLOCKOUT)        |
| Stop             | Doze                     | 320 μA                             | 600 μA, typ. (no CLOCKOUT)        |
| VLLS1            | Low power /<br>Hibernate | 0.6 μΑ                             | <1 µA <sup>1</sup>                |
| VLLS0            | Reset /<br>Powerdown     | <250 nA                            | <30 nA                            |
| Run <sup>2</sup> | Transmit                 | 12 mA                              | 15 mA                             |
| Run <sup>3</sup> | Receive                  | 12 mA                              | 15 mA                             |

#### Table 7. Power Modes

<sup>1</sup> Value does not include SPI activity.

<sup>2</sup> 32 MHz operation

<sup>3</sup> 32 MHz operation

Table 7 describes alignment of radio and MCU power modes versus current consumption for typical conditions: VBAT / VDD = + 2.7V @ T=25°C

## 7 MKW2xDxxxV electrical characteristics

### 7.1 Recommended operating conditions

#### Table 8. Recommended operating conditions

| Characteristic  | Symbol                                   | Min           | Тур | Max           | Unit |
|---|--|---------------|-----|---------------|------|
| Power Supply Voltage (V <sub>BATT</sub> = VDD <sub>INT</sub> )  | V <sub>BATT,</sub><br>VDD <sub>INT</sub> | 1.8           | 2.7 | 3.6           | Vdc  |
| Input Frequency   | fin                                      | 2.360         | _   | 2.480         | GHz  |
| Ambient Temperature Range   | TA                                       | -40           | 25  | 105           | °C   |
| Logic Input Voltage Low   | VIL                                      | 0             | —   | 30%<br>VDDINT | V    |
| Logic Input Voltage High  | VIH                                      | 70%<br>VDDINT | _   | VDDINT        | V    |
| SPI Clock Rate  | f <sub>SPI</sub>                         | —             |     | 16.0          | MHz  |
| RF Input Power  | Pmax                                     | —             | _   | 10            | dBm  |
| Crystal Reference Oscillator Frequency ( $\pm 40$ ppm over operating conditions to meet the 802.15.4 Standard.) | fref                                     | 32 MHz only   |     |               |      |

### 7.2 Thermal handling ratings

| Symbol           | Description                   | Min. | Max. | Unit | Nots |
|------------------|-------------------------------|------|------|------|------|
| T <sub>STG</sub> | Storage temperature           | -55  | 150  | °C   | 1    |
| T <sub>SDR</sub> | Solder temperature, lead-free | —    | 260  | °C   | 2    |

<sup>1</sup> Determined according to JEDEC Standard JESD22-A103, *High Temperature Storage Life*.

<sup>2</sup> Determined according to IPC/JEDEC Standard J-STD-020, Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices.

### 7.3 Moisture handling ratings

| Symbol | Description                 | Min. | Max. | Unit | Nots |
|--------|-----------------------------|------|------|------|------|
| MSL    | Moisture sensitivitiy level | —    | 3    | _    | 1    |

<sup>1</sup> Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic* Solid State Surface Mount Devices.

### 7.4 ESD handling ratings

| Symbol           | Description   | Min.  | Max. | Unit | Nots |
|------------------|---|-------|------|------|------|
| V <sub>HBM</sub> | Electrostatic discharge voltage, human body model     | -2000 | 2000 | V    | 1    |
| V <sub>CDM</sub> | Electrostatic discharge voltage, charged-device model | -500  | 500  | V    | 2    |
| I <sub>LAT</sub> | Latch-up current at ambient temperature of 105°C      | -100  | 100  | mA   |      |

<sup>1</sup> Determined according to JEDEC Standard JESD22-A103, *High Temperature Storage Life*.

<sup>2</sup> Determined according to IPC/JEDEC Standard J-STD-020, Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices.

### 7.5 Voltage and current ratings

| Symbol              | Description   | Min.                  | Max.                  | Unit |
|---------------------|---|-----------------------|-----------------------|------|
| V <sub>DD</sub>     | Digital supply voltage                                      | -0.3                  | 3.8                   | V    |
| I <sub>DD</sub>     | Digital supply current                                      |                       | 155                   | mA   |
| V <sub>DIO</sub>    | Digital input voltage (except RESET, EXTAL, and XTAL)       | -0.3                  |                       | V    |
| V <sub>AIO</sub>    | Analog <sup>1</sup> , RESET, EXTAL, and XTAL input voltage  | -0.3                  | V <sub>DD</sub> + 0.3 | V    |
| ۱ <sub>D</sub>      | Maximum current single pin limit (applies to all port pins) | -25                   | 25                    | mA   |
| V <sub>DDA</sub>    | Analog supply voltage                                       | V <sub>DD</sub> – 0.3 | V <sub>DD</sub> + 0.3 | V    |
| V <sub>USB_DP</sub> | USB_DP input voltage  | -0.3                  | 3.63                  | V    |
| V <sub>USB_DM</sub> | USB_DM input voltage  | -0.3                  | 3.63                  | V    |
| VREGIN              | USB regulator input   | -0.3                  | 6                     | V    |
| V <sub>BAT</sub>    | RTC battery supply voltage                                  | -0.3                  | 3.8                   | V    |

<sup>1</sup> Analog pins are defined as pins that do not have an associated general purpose I/O port function.

### 7.5.1 EMC radiated emissions operating behaviors

| Symbol           | Description                        | Frequency<br>band (MHz) | Тур. | Unit | Notes |
|------------------|------------------------------------|-------------------------|------|------|-------|
| V <sub>RE1</sub> | Radiated emissions voltage, band 1 | 0.15-50                 | TBD  | dBµV | 1,2   |
| V <sub>RE2</sub> | Radiated emissions voltage, band 2 | 50-150                  | TBD  | dBµV |       |
| V <sub>RE3</sub> | Radiated emissions voltage, band 3 | 150-500                 | TBD  | dBµV |       |
| V <sub>RE4</sub> | Radiated emissions voltage, band 4 | 500-1000                | TBD  | dBµV |       |
| VRE_IEC          | IEC level                          | 0.15-1000               | TBD  | -    | 2, 3  |

- Determined according to IEC Standard 61967-1, Integrated Circuits Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions and IEC Standard 61967-2, Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method. Measurements were made while the microcontroller was running basic application code. The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.
- 2.  $V_{DD}$  = 3.3 V,  $T_A$  = 25 °C,  $f_{OSC}$  = 12 MHz (crystal),  $f_{SYS}$  = 48 MHz,  $f_{BUS}$  = 48MHz
- Specified according to Annex D of IEC Standard 61967-2, Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method

### 7.5.2 Designing with radiated emissions in mind

To find application notes that provide guidance on designing your system to minimize interference from radiated emissions:

- 1. Go to http://www.freescale.com.
- 2. Perform a keyword search for "EMC design."

### 7.5.3 Capacitance attributes

| Symbol            | Description                     | Min. | Max. | Unit |
|-------------------|---------------------------------|------|------|------|
| C <sub>IN_A</sub> | Input capacitance: analog pins  | -    | 7    | pF   |
| C <sub>IN_D</sub> | Input capacitance: digital pins | -    | 7    | pF   |

## 8 MCU Electrical characteristics

### 8.1 Maximum ratings

#### Table 9. Maximum ratings

| Requirement               | Description                  | Symbol                      | Rating level                         | Unit |
|---------------------------|------------------------------|-----------------------------|--------------------------------------|------|
| Power Supply Voltage      |                              | VBAT, VBAT2                 | -0.3 to 3.6                          | Vdc  |
| Digital Input Voltage     |                              | Vin                         | -0.3 to (VDDINT + 0.3)               | Vdc  |
| RF Input Power            |                              | Pmax                        | +10                                  | dBm  |
|                           | Human Body Model             | HBM                         | ±2000                                | Vdc  |
| ESD <sup>1</sup>          | Machine Model                | MM                          | ±200                                 | Vdc  |
|                           | Charged Device Model         | CDM                         | ±750                                 | Vdc  |
|                           | Power Electro-Static         |                             | No damage / latch up to<br>±4000     | Vdc  |
|                           | Discharge / Direct Contact   |                             | No soft failure / reset to<br>±1000  | vac  |
|                           | Power Electro-Static         | - PESD                      | No damage / latch up to<br>±6000     | Vdc  |
| EMC <sup>2</sup>          | Discharge / Indirect Contact |                             | No soft failure / reset to<br>±1000  | vac  |
|                           |                              |                             | No damage / latch up to $\pm 5$      | Vdc  |
|                           | Langer IC / EFT / P201       | EFT (Electro                | No soft failure / reset to $\pm 5$   | Vúc  |
|                           | Langer IC / EFT / P201       | Magnetic Fast<br>Transient) | No damage / latch up to<br>±300      | Vdc  |
|                           |                              |                             | No soft failure / reset to $\pm 150$ |      |
| Junction Temperature      |                              | TJ                          | +150                                 | °C   |
| Storage Temperature Range |                              | T <sub>stg</sub>            | -65 to +165                          | °C   |

#### NOTE

Maximum ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the limits in the electrical characteristics or recommended operating conditions tables.

<sup>1</sup> Electrostatic discharge on all device pads meet this requirement

<sup>2</sup> Electromagnetic compatibility for this product is low stress rating level

### 8.2 General

### 8.2.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.

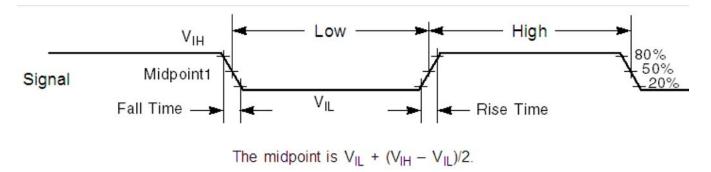


Figure 2. Input signal measurement reference

All digital I/O switching characteristics assume:

- output pins
  - have CL=30pF loads,
  - are configured for fast slew rate (PORTx\_PCRn[SRE]=0), and
  - are configured for high drive strength (PORTx\_PCRn[DSE]=1)
- input pins
  - have their passive filter disabled (PORTx\_PCRn[PFE]=0)

#### Nonswitching electrical specifications 8.2.2

#### 8.2.2.1 Voltage and current operating requirements

1

| Symbol                             | Description  | Min.                   | Max.  | Unit   | Notes |
|------------------------------------|--|------------------------|---|--------|-------|
| V <sub>DD</sub>                    | Supply voltage   | 1.71                   | 3.6   | V      |       |
| VDDA                               | Analog supply voltage  | 1.71                   | 3.6   | V      |       |
| V <sub>DD</sub> - V <sub>DDA</sub> | V <sub>DD</sub> -to-V <sub>DDA</sub> differential voltage  | -0.1                   | 0.1   | V      |       |
| V <sub>SS</sub> - V <sub>SSA</sub> | V <sub>SS</sub> -to-V <sub>SSA</sub> differential voltage  | -0.1                   | 0.1   | V      |       |
| VBAT                               | RTC battery supply voltage   | 1.71                   | 3.6   | V      |       |
| VIH                                | Input high voltage<br>• 2.7 V $\leq$ V <sub>DD</sub> $\leq$ 3.6 V  | 0.7 × V <sub>DD</sub>  |   | v      |       |
|                                    | • $1.7 \text{ V} \le \text{V}_{\text{DD}} \le 2.7 \text{ V}$   | 0.75 × V <sub>DD</sub> | -   | v      |       |
| V <sub>IL</sub>                    | Input low voltage<br>• 2.7 V ≤ V <sub>DD</sub> ≤ 3.6 V<br>• 1.7 V ≤ V <sub>DD</sub> ≤ 2.7 V  |                        | $0.35 \times V_{DD}$<br>$0.3 \times V_{DD}$ | V<br>V |       |
| VHYS                               | Input hysteresis   | $0.06 \times V_{DD}$   | _   | V      |       |
| I <sub>ICIO</sub>                  | <ul> <li>I/O pin DC injection current — single pin</li> <li>V<sub>IN</sub> &lt; V<sub>SS</sub>-0.3V (Negative current injection)</li> <li>V<sub>IN</sub> &gt; V<sub>DD</sub>+0.3V (Positive current injection)</li> </ul>          | -3                     | <br>+3                                      | mA     | 1     |
| I <sub>ICcont</sub>                | Contiguous pin DC injection current —regional limit,<br>includes sum of negative injection currents or sum of<br>positive injection currents of 16 contiguous pins<br>• Negative current injection<br>• Positive current injection | -25<br>—               | <br>+25                                     | mA     |       |
| VRAM                               | V <sub>DD</sub> voltage required to retain RAM   | 1.2                    | -   | V      |       |
| VREVBAT                            | V <sub>BAT</sub> voltage required to retain the VBAT register file   | VPOR_VBAT              | —   | V      |       |

<sup>1.</sup> All analog pins are internally clamped to Vss and VDD through ESD protection diodes. If VIN is greater than VAIO\_MIN (=Vss-0.3V) and VIN is less than VAIO\_MAX(=VDD+0.3V) is observed, then there is no need to provide current limiting resistors at the pads. If these limits cannot be observed then a current limiting resistor is required. The negative DC injection current limiting resistor is calculated as R=(VAIO\_MIN-VIN)/|IIC|. The positive injection current limiting resistor is calcualted as R=(VIN-VAIO\_MAX)/|IIC|. Select the larger of these two calculated resistances.

### 8.3 LVD and POR operating requirements

| Symbol             | Description   | Min. | Тур. | Max. | Unit | Notes |
|--------------------|---|------|------|------|------|-------|
| VPOR               | Falling VDD POR detect voltage                              | 0.8  | 1.1  | 1.5  | V    |       |
| V <sub>LVDH</sub>  | Falling low-voltage detect threshold — high range (LVDV=01) | 2.48 | 2.56 | 2.64 | V    |       |
|                    | Low-voltage warning thresholds — high range                 |      |      |      |      | 1     |
| V <sub>LVW1H</sub> | Level 1 falling (LVWV=00)                                   | 2.62 | 2.70 | 2.78 | V    |       |
| V <sub>LVW2H</sub> | Level 2 falling (LVWV=01)                                   | 2.72 | 2.80 | 2.88 | V    |       |
| V <sub>LVW3H</sub> | Level 3 falling (LVWV=10)                                   | 2.82 | 2.90 | 2.98 | V    |       |
| V <sub>LVW4H</sub> | Level 4 falling (LVWV=11)                                   | 2.92 | 3.00 | 3.08 | V    |       |
| V <sub>HYSH</sub>  | Low-voltage inhibit reset/recover hysteresis — high range   | _    | ±80  | -    | mV   |       |
| V <sub>LVDL</sub>  | Falling low-voltage detect threshold — low range (LVDV=00)  | 1.54 | 1.60 | 1.66 | V    |       |
|                    | Low-voltage warning thresholds - low range                  |      |      |      |      | 1     |
| V <sub>LVW1L</sub> | Level 1 falling (LVWV=00)                                   | 1.74 | 1.80 | 1.86 | V    |       |
| V <sub>LVW2L</sub> | Level 2 falling (LVWV=01)                                   | 1.84 | 1.90 | 1.96 | V    |       |
| V <sub>LVW3L</sub> | Level 3 falling (LVWV=10)                                   | 1.94 | 2.00 | 2.06 | V    |       |
| V <sub>LVW4L</sub> | Level 4 falling (LVWV=11)                                   | 2.04 | 2.10 | 2.16 | V    |       |
| V <sub>HYSL</sub>  | Low-voltage inhibit reset/recover hysteresis —<br>low range | _    | ±60  | -    | mV   |       |
| V <sub>BG</sub>    | Bandgap voltage reference                                   | 0.97 | 1.00 | 1.03 | V    |       |
| t <sub>LPO</sub>   | Internal low power oscillator period — factory trimmed      | 900  | 1000 | 1100 | μs   |       |

#### 1. Rising thresholds are falling threshold + hysteresis voltage.

#### VBAT power operating requirements

| Symbol                | Description                            | Min. | Тур. | Max. | Unit | Notes |
|-----------------------|--|------|------|------|------|-------|
| V <sub>POR_VBAT</sub> | Falling VBAT supply POR detect voltage | 0.8  | 1.1  | 1.5  | V    |       |

### 8.3.1 Voltage and current operating behaviors

| Symbol           | Description   | Min.                  | Max. | Unit | Notes |
|------------------|---|-----------------------|------|------|-------|
| VOH              | Output high voltage — high drive strength                               |                       |      |      |       |
|                  | • 2.7 V $\leq$ V <sub>DD</sub> $\leq$ 3.6 V, I <sub>OH</sub> = - 9 mA   | V <sub>DD</sub> - 0.5 | _    | V    |       |
|                  | + 1.71 V $\leq$ V_{DD} $\leq$ 2.7 V, I_{OH} = -3 mA                     | V <sub>DD</sub> - 0.5 | —    | V    |       |
|                  | Output high voltage — low drive strength                                |                       |      |      |       |
|                  | • 2.7 V $\leq$ V <sub>DD</sub> $\leq$ 3.6 V, I <sub>OH</sub> = -2 mA    | V <sub>DD</sub> - 0.5 | -    | V    |       |
|                  | • 1.71 V $\leq$ V <sub>DD</sub> $\leq$ 2.7 V, I <sub>OH</sub> = -0.6 mA | V <sub>DD</sub> - 0.5 | ·    | V    |       |
| I <sub>OHT</sub> | Output high current total for all ports                                 | - 1                   | 100  | mA   |       |
| VOL              | Output low voltage — high drive strength                                |                       |      |      |       |
|                  | • 2.7 V $\leq$ V <sub>DD</sub> $\leq$ 3.6 V, I <sub>OL</sub> = 9 mA     | _                     | 0.5  | V    |       |
|                  | • 1.71 V $\leq$ V <sub>DD</sub> $\leq$ 2.7 V, I <sub>OL</sub> = 3 mA    | -                     | 0.5  | V    |       |
|                  | Output low voltage - low drive strength                                 |                       |      | 5    |       |
|                  | • 2.7 V $\leq$ V <sub>DD</sub> $\leq$ 3.6 V, I <sub>OL</sub> = 2 mA     | -                     | 0.5  | V    |       |
|                  | + 1.71 V $\leq$ V_{DD} $\leq$ 2.7 V, I_{OL} = 0.6 mA                    | -                     | 0.5  | V    |       |
| IOLT             | Output low current total for all ports                                  | -                     | 100  | mA   |       |
| I <sub>IN</sub>  | Input leakage current (per pin)   |                       |      |      |       |
|                  | @ full temperature range  | —                     | 1.0  | μA   | 1     |
|                  | • @ 25 °C   | -                     | 0.1  | μA   |       |
| loz              | Hi-Z (off-state) leakage current (per pin)                              |                       | 1    | μA   |       |
| loz              | Total Hi-Z (off-state) leakage current (all input pins)                 | -                     | 4    | μA   |       |
| R <sub>PU</sub>  | Internal pullup resistors   | 22                    | 50   | kΩ   | 2     |
| R <sub>PD</sub>  | Internal pulldown resistors   | 22                    | 50   | kΩ   | 3     |

1. Tested by ganged leakage method

2. Measured at Vinput = V<sub>SS</sub>

3. Measured at Vinput = V<sub>DD</sub>

### 8.3.2 Power mode transition operating behaviors

All specifications except tPOR, and VLLSx to RUN recovery times in the following table assume this clock configuration:

- CPU and system clocks = 50 MHz
- Bus clock = 50 MHz
- Flash clock = 25 MHz

| Symbol           | Description  | Min.        | Max. | Unit | Notes |
|------------------|--|-------------|------|------|-------|
| t <sub>POR</sub> | After a POR event, amount of time from the point $V_{DD}$ reaches 1.71 V to execution of the first instruction across the operating temperature range of the chip. | 1. <u> </u> | 300  | μs   |       |
|                  | VLLS0 → RUN  | _           | 130  | μs   |       |
|                  | VLLS1 → RUN  | -           | 130  | μs   |       |
|                  | VLLS2 → RUN  | -           | 70   | μs   |       |
|                  | VLLS3 → RUN  | -           | 70   | μs   |       |
|                  | • LLS $\rightarrow$ RUN  | 2 <b></b> 2 | 6    | μs   |       |
|                  | <ul> <li>VLPS → RUN</li> </ul>   | 5 <b>-</b>  | 5.2  | μs   |       |
|                  | <ul> <li>STOP → RUN</li> </ul>   | 2. <b></b>  | 5.2  | μs   |       |

### 8.3.3 Power consumption operating behaviors

| Symbol  | Description  | Min. | Тур. | Max.     | Unit | Notes |
|---------|--|------|------|----------|------|-------|
| IDDA    | Analog supply current  | _    | -    | See note | mA   | 1     |
| IDD_RUN | Run mode current — all peripheral clocks disabled, code executing from flash   |      |      |          |      | 2     |
|         | • @ 1.8V   | -    | TBD  | TBD      | mA   |       |
|         | • @ 3.0V   | _    | 17   | TBD      | mA   |       |
| DD_RUN  | Run mode current — all peripheral clocks<br>enabled, code executing from flash |      |      |          |      | 3, 4  |
|         | • @ 1.8V<br>• @ 3.0V   | _    | TBD  | TBD      | mA   |       |
|         | • @ 25°C   | _    | 24   | TBD      | mA   |       |
|         | • @ 125°C  | _    | TBD  | TBD      | mA   |       |
| DD_WAIT | Wait mode high frequency current at 3.0 V — all peripheral clocks disabled     | -    | 12.3 | TBD      | mA   | 2     |
| DD_WAIT | Wait mode reduced frequency current at 3.0 V — all peripheral clocks disabled  | -    | TBD  | TBD      | mA   | 5     |
| DD_STOP | Stop mode current at 3.0 V   | —    | 200  | TBD      | μA   |       |
| DD_VLPR | Very-low-power run mode current at 3.0 V — all peripheral clocks disabled      | -    | 1    | TBD      | mA   | 6     |

Table continues on the next page ...

| Symbol                | Description   | Min.         | Тур. | Max. | Unit | Notes |
|-----------------------|---|--------------|------|------|------|-------|
| IDD_VLPR              | Very-low-power run mode current at 3.0 V — all<br>peripheral clocks enabled   |              | TBD  | TBD  | mA   | 7     |
| DD_VLPW               | Very-low-power wait mode current at 3.0 V   | 1            | 700  | TBD  | μA   | 8     |
| DD_VLPS               | Very-low-power stop mode current at 3.0 V   | 5 <b></b> .2 | 6.3  | TBD  | μA   |       |
| I <sub>DD_LLS</sub>   | Low leakage stop mode current at 3.0 V<br>• @ -40 to 25°C<br>• @ 50°C<br>• @ 70°C<br>• @ 105°C  | 1            | 3.2  | TBD  | μA   |       |
| I <sub>DD_VLLS3</sub> | Very low-leakage stop mode 3 current at 3.0 V<br>• @ -40 to 25°C<br>• @ 50°C<br>• @ 70°C<br>• @ 105°C                                     | _            | 2.6  | TBD  | μA   |       |
| IDD_VLLS2             | Very low-leakage stop mode 2 current at 3.0 V<br>• @ -40 to 25°C<br>• @ 50°C<br>• @ 70°C<br>• @ 105°C                                     | -            | 0.8  | TBD  | nA   |       |
| IDD_VLLS1             | Very low-leakage stop mode 1 current at 3.0 V<br>• @ -40 to 25°C<br>• @ 50°C<br>• @ 70°C<br>• @ 105°C                                     |              | 0.6  | TBD  | nA   |       |
| IDD_VLLS0             | Very low-leakage stop mode 0 current at 3.0 V<br>with POR detect circuit enabled<br>• @ -40 to 25°C<br>• @ 50°C<br>• @ 70°C<br>• @ 105°C  | Ι            | 0.4  | TBD  | nA   |       |
| IDD_VLLS0             | Very low-leakage stop mode 0 current at 3.0 V<br>with POR detect circuit disabled<br>• @ -40 to 25°C<br>• @ 50°C<br>• @ 70°C<br>• @ 105°C | —            | 0.2  | TBD  | nA   |       |
| I <sub>DD_VBAT</sub>  | Average current when CPU is not accessing RTC<br>registers at 3.0 V<br>• @ -40 to 25°C<br>• @ 50°C<br>• @ 70°C<br>• @ 105°C               |              | 0.8  | TBD  | nA   | 9     |

- 1. The analog supply current is the sum of the active or disabled current for each of the analog modules on the device. See each module's specification for its supply current.
- 50MHz core and system clock, 25MHz bus clock, and 25MHz flash clock . MCG configured for FEI mode. All peripheral clocks disabled.
- 50MHz core and system clock, 25MHz bus clock, and 25MHz flash clock. MCG configured for FEI mode. All peripheral clocks enabled, and peripherals are in active operation.
- 4. Max values are measured with CPU executing DSP instructions
- 5. 25MHz core and system clock, 25MHz bus clock, and 12.5MHz flash clock. MCG configured for FEI mode.

- 2 MHz core, system, and bus clock and 1MHz flash clock. MCG configured for BLPE mode. All peripheral clocks disabled. Code executing from flash.
- 7. 2 MHz core, system, and bus clock and 1MHz flash clock. MCG configured for BLPE mode. All peripheral clocks enabled but peripherals are not in active operation. Code executing from flash.
- 8. 2 MHz core, system, and bus clock and 1MHz flash clock. MCG configured for BLPE mode. All peripheral clocks disabled.
- 9. Includes 32kHz oscillator current and RTC operation.

### 8.4 Switching specification

### 8.4.1 Device clock specifications

| Symbol             | Description   | Min. | Max. | Unit | Notes |
|--------------------|---|------|------|------|-------|
|                    | Normal run mod  | e    |      |      |       |
| fsys               | System and core clock                                     | -    | 50   | MHz  |       |
|                    | System and core clock when Full Speed USB in<br>operation | 20   | -    | MHz  |       |
| f <sub>BUS</sub>   | Bus clock   | -    | 50   | MHz  |       |
| f <sub>FLASH</sub> | Flash clock   | -    | 25   | MHz  |       |
| <b>f</b> LPTMR     | LPTMR clock   | -    | 25   | MHz  |       |
|                    | VLPR mode <sup>1</sup>                                    |      |      |      |       |
| fsys               | System and core clock                                     | -    | 4    | MHz  |       |
| f <sub>BUS</sub>   | Bus clock   | -    | 4    | MHz  |       |
| f <sub>FLASH</sub> | Flash clock   | -    | 1    | MHz  |       |
| <b>f</b> ERCLK     | External reference clock                                  | -    | 16   | MHz  |       |
| fLPTMR_pin         | LPTMR clock   | -    | 25   | MHz  |       |
| LPTMR_ERCLK        | LPTMR external reference clock                            | -    | 16   | MHz  |       |
| fi2S_MCLK          | I2S master clock  | -    | 12.5 | MHz  |       |
| fI2S_BCLK          | I2S bit clock   | -    | 4    | MHz  |       |

1. The frequency limitations in VLPR mode here override any frequency specification listed in the timing specification for any other module.

### 8.4.2 General switching specifications

These general purpose specifications apply to all signals configured for GPIO, UART, CMT, and  $I^2C$  signals.

| Symbol | Description   | Min.       | Max. | Unit                | Notes |
|--------|---|------------|------|---------------------|-------|
|        | GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path                          | 1.5        | -    | Bus clock<br>cycles | 1, 2  |
|        | GPIO pin interrupt pulse width (digital glitch filter disabled, analog filter enabled) — Asynchronous path  | 100        | —    | ns                  | 3     |
|        | GPIO pin interrupt pulse width (digital glitch filter disabled, analog filter disabled) — Asynchronous path | 50         | -    | ns                  | 3     |
|        | External reset pulse width (digital glitch filter disabled)   | 100        | -    | ns                  | 3     |
|        | Mode select (EZP_CS) hold time after reset deassertion  | 2          |      | Bus clock<br>cycles |       |
|        | Port rise and fall time (high drive strength)   |            |      |                     | 4     |
|        | Slew disabled   |            |      |                     |       |
|        | <ul> <li>1.71 ≤ V<sub>DD</sub> ≤ 2.7V</li> </ul>  | -          | 13   | ns                  |       |
|        | <ul> <li>2.7 ≤ V<sub>DD</sub> ≤ 3.6V</li> </ul>   | _          |      | ns                  |       |
|        | Slew enabled  |            | 7    |                     |       |
|        | <ul> <li>1.71 ≤ V<sub>DD</sub> ≤ 2.7V</li> </ul>  | _          |      | ns                  |       |
|        | <ul> <li>2.7 ≤ V<sub>DD</sub> ≤ 3.6V</li> </ul>   | _          | 36   | ns                  |       |
|        | 1   |            | 24   |                     | 5     |
|        | Port rise and fall time (low drive strength)  |            |      |                     | 5     |
|        | Slew disabled   |            |      |                     |       |
|        | <ul> <li>1.71 ≤ V<sub>DD</sub> ≤ 2.7V</li> </ul>  | _          | 12   | ns                  |       |
|        | <ul> <li>2.7 ≤ V<sub>DD</sub> ≤ 3.6V</li> </ul>   | _          | 6    | ns                  |       |
|        | Slew enabled  |            |      |                     |       |
|        | <ul> <li>1.71 ≤ V<sub>DD</sub> ≤ 2.7V</li> </ul>  | 2. <u></u> | 36   | ns                  |       |
|        | <ul> <li>2.7 ≤ V<sub>DD</sub> ≤ 3.6V</li> </ul>   | -          | 24   | ns                  |       |

 This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In Stop, VLPS, LLS, and VLLSx modes, the synchronizer is bypassed so shorter pulses can be recognized in that case.

2. The greater synchronous and asynchronous timing must be met.

3. This is the minimum pulse width that is guaranteed to be recognized as a pin interrupt request in Stop, VLPS, LLS, and VLLSx modes.

4. 75pF load

5. 15pF load

### 8.5 Core modules

### 8.5.1 JTAG electricals

| Symbol            | Description  | Min. | Max. | Unit |
|-------------------|--|------|------|------|
|                   | Operating voltage                                  | 2.7  | 5.5  | V    |
| J1                | TCLK frequency of operation                        |      |      | MHz  |
|                   | • JTAG   |      | 10   |      |
|                   | • CJTAG  |      | 5    |      |
| J2                | TCLK cycle period                                  | 1/J1 | _    | ns   |
| J3                | TCLK clock pulse width                             |      |      |      |
|                   | • JTAG   | 100  | -    | ns   |
|                   | • CJTAG  | 200  | -    | ns   |
|                   |  |      |      | ns   |
| J4                | TCLK rise and fall times                           |      | 1    | ns   |
| J5                | TMS input data setup time to TCLK rise             | 53   | _    | ns   |
|                   | • JTAG<br>• CJTAG                                  | 112  | _    |      |
| J6                | TDI input data setup time to TCLK rise             | 8    | -    | ns   |
| J7                | TMS input data hold time after TCLK rise<br>• JTAG | 3.4  | _    | ns   |
|                   | • CJTAG  | 3.4  |      |      |
| J8                | TDI input data hold time after TCLK rise           | 3.4  | -    | ns   |
| <mark>.</mark> ]9 | TCLK low to TMS data valid<br>• JTAG               | -    | 48   | ns   |
|                   | • CJTAG  | -    | 85   |      |
| J10               | TCLK low to TDO data valid                         | —    | 48   | ns   |
| J11               | Output data hold/invalid time after clock edge1    |      | 3    | ns   |

1. They are common for JTAG and CJTAG. Input transition = 1 ns and Output load = 50pf

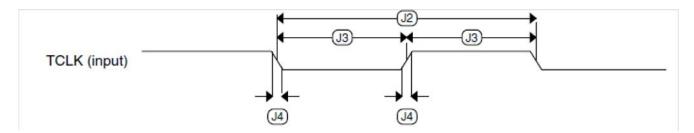


Figure 3. Test clock input timing

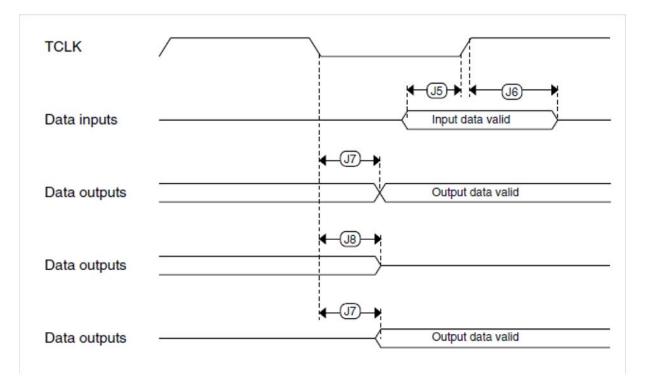
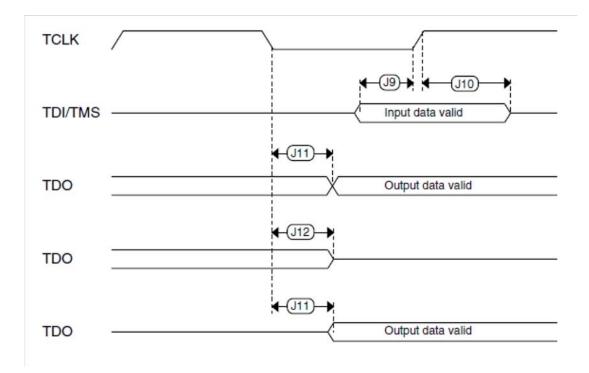
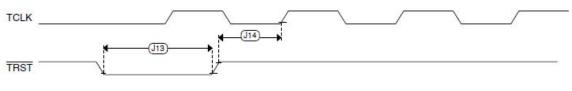


Figure 4. Boundary scan (JTAG) timing









### 8.6 Clock modules

| Symbol                  | Description                               |  | Min.                            | Тур.      | Max.    | Unit              | Notes |
|-------------------------|---|--|---------------------------------|-----------|---------|-------------------|-------|
| f <sub>ints_ft</sub>    |   | frequency (slow clock) —<br>nominal VDD and 25 °C                | -                               | 32.768    |         | kHz               |       |
| f <sub>ints_t</sub>     | Internal reference trimmed                | frequency (slow clock) — user                                    | 31.25                           |           | 39.0625 | kHz               |       |
| ∆ <sub>fdco_res_t</sub> |   | ned average DCO output<br>voltage and temperature —<br>d SCFTRIM | _                               | ± 0.3     | ± 0.6   | %f <sub>dco</sub> | 1     |
| ∆f <sub>dco_res_t</sub> |   | ned average DCO output<br>voltage and temperature —<br>y         | -                               | ± 0.2     | ± 0.5   | %f <sub>dco</sub> | 1     |
| $\Delta f_{dco_t}$      |   | rimmed average DCO output<br>tage and temperature                | -                               | +0.5/-0.7 | ±3      | %f <sub>dco</sub> | 1     |
| ∆f <sub>dco_t</sub>     |   | rimmed average DCO output<br>ed voltage and temperature          | -                               | ± 0.3     | TBD     | %f <sub>dco</sub> | 1     |
| fintf_ft                |   | frequency (fast clock) —<br>nominal VDD and 25°C                 | -                               | 4         |         | MHz               |       |
| f <sub>intf_t</sub>     | Internal reference<br>trimmed at nomina   | frequency (fast clock) — user<br>II VDD and 25 °C                | 3                               | -         | 5       | MHz               |       |
| floc_low                | Loss of external cle<br>RANGE = 00        | ock minimum frequency —  | (3/5) x<br>f <sub>ints_t</sub>  | -         |         | kHz               |       |
| f <sub>loc_high</sub>   | Loss of external clo<br>RANGE = 01, 10, 0 | ock minimum frequency —<br>or 11                                 | (16/5) x<br>f <sub>ints_t</sub> | 1.<br>    |         | kHz               |       |
|                         |   | F  | LL                              |           |         |                   |       |
| f <sub>fll_ref</sub>    | FLL reference freq                        | uency range  | 31.25                           | -         | 39.0625 | kHz               |       |
| f <sub>dco</sub>        | DCO output<br>frequency range             | Low range (DRS=00)<br>640 × f <sub>fil_ref</sub>                 | 20                              | 20.97     | 25      | MHz               | 2, 3  |
|                         |   | Mid range (DRS=01)<br>1280 × f <sub>fll_ref</sub>                | 40                              | 41.94     | 50      | MHz               | 1     |
|                         |   | Mid-high range (DRS=10)<br>1920 × f <sub>fll_ref</sub>           | 60                              | 62.91     | 75      | MHz               |       |
|                         |   | High range (DRS=11)<br>2560 × f <sub>fll_ref</sub>               | 80                              | 83.89     | 100     | MHz               |       |
| dco_t_DMX32             | DCO output<br>frequency                   | Low range (DRS=00)<br>732 × f <sub>fil_ref</sub>                 |                                 | 23.99     |         | MHz               | 4, 5  |
|                         |   | Mid range (DRS=01)<br>1464 × f <sub>fll_ref</sub>                |                                 | 47.97     |         | MHz               |       |
|                         |   | Mid-high range (DRS=10)<br>2197 × f <sub>fll_ref</sub>           | 1-1                             | 71.99     |         | MHz               |       |
|                         |   | High range (DRS=11)<br>2929 × f <sub>fll_ref</sub>               | -                               | 95.98     | -       | MHz               |       |

| Symbol                   | Description  | Min.   | Тур. | Max.  | Unit | Notes |
|--------------------------|--|--------|------|---|------|-------|
| J <sub>cyc_fll</sub>     | FLL period jitter  | _      | 180  | _   | ps   |       |
|                          | <ul> <li>f<sub>VCO</sub> = 48 MHz</li> <li>f<sub>VCO</sub> = 98 MHz</li> </ul>   | _      | 150  | _   |      |       |
| t <sub>fll_acquire</sub> | FLL target frequency acquisition time  | _      | _    | 1   | ms   | 6     |
|                          | P  | LL     |      |   |      |       |
| f <sub>vco</sub>         | VCO operating frequency  | 48.0   | _    | 100   | MHz  |       |
| I <sub>pli</sub>         | PLL operating current<br>• PLL @ 96 MHz (f <sub>osc_hi_1</sub> = 8 MHz, f <sub>pll_ref</sub> =<br>2 MHz, VDIV multiplier = 48) | _      | 1060 | _   | μA   | 7     |
| I <sub>pli</sub>         | PLL operating current<br>• PLL @ 48 MHz (f <sub>osc_hi_1</sub> = 8 MHz, f <sub>pll_ref</sub> =<br>2 MHz, VDIV multiplier = 24) | _      | 600  | _   | μA   | 7     |
| f <sub>pll_ref</sub>     | PLL reference frequency range  | 2.0    | _    | 4.0   | MHz  |       |
| J <sub>cyc_pll</sub>     | PLL period jitter (RMS)  |        |      |   |      | 8     |
|                          | <ul> <li>f<sub>vco</sub> = 48 MHz</li> </ul>   | _      | 120  | —   | ps   |       |
|                          | • f <sub>vco</sub> = 100 MHz   | _      | 50   | _   | ps   |       |
| J <sub>acc_pll</sub>     | PLL accumulated jitter over 1µs (RMS)  |        |      |   |      | 8     |
|                          | <ul> <li>f<sub>vco</sub> = 48 MHz</li> </ul>   | _      | 1350 | _   | ps   |       |
|                          | • f <sub>vco</sub> = 100 MHz   | _      | 600  | -   | ps   |       |
| Dlock                    | Lock entry frequency tolerance   | ± 1.49 | _    | ± 2.98  | %    |       |
| D <sub>unl</sub>         | Lock exit frequency tolerance  | ± 4.47 | _    | ± 5.97  | %    |       |
| t <sub>pll_lock</sub>    | Lock detector detection time   | _      | _    | 150 × 10 <sup>-6</sup><br>+ 1075(1/<br>f <sub>pll_ref</sub> ) | S    | 9     |

1. This parameter is measured with the internal reference (slow clock) being used as a reference to the FLL (FEI clock mode).

- 2. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32=0.
- The resulting system clock frequencies should not exceed their maximum specified values. The DCO frequency deviation (Δf<sub>dco t</sub>) over voltage and temperature should be considered.
- 4. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32=1.
- 5. The resulting clock frequency must not exceed the maximum specified clock frequency of the device.
- This specification applies to any time the FLL reference source or reference divider is changed, trim value is changed, DMX32 bit is changed, DRS bits are changed, or changing from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.
- 7. Excludes any oscillator currents that are also consuming power while PLL is in operation.
- 8. This specification was obtained using a Freescale developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary.
- This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

# 8.6.1 Oscillator electrical specifications

| Symbol          | Description   | Min.        | Тур. | Max. | Unit | Note |
|-----------------|---|-------------|------|------|------|------|
| V <sub>DD</sub> | Supply voltage  | 1.71        |      | 3.6  | V    |      |
| DDOSC           | Supply current — low-power mode (HGO=0)                       |             |      |      |      | 1    |
|                 | • 32 kHz  | -           | 500  | -    | nA   |      |
|                 | • 4 MHz   | _           | 200  | -    | μA   |      |
|                 | • 8 MHz (RANGE=01)  | _           | 300  | _    | μA   |      |
|                 | • 16 MHz  | _           | 950  | _    | μA   |      |
|                 | • 24 MHz  | _           | 1.2  | _    | mA   |      |
|                 | • 32 MHz  |             | 1.5  | -    | mA   |      |
| DDOSC           | Supply current — high gain mode (HGO=1)                       |             |      |      |      | 1    |
|                 | • 32 kHz  | _           | 25   | -    | μA   |      |
|                 | • 4 MHz   |             | 400  | —    | μA   |      |
|                 | <ul> <li>8 MHz (RANGE=01)</li> </ul>                          | <del></del> | 500  | —    | μA   |      |
|                 | • 16 MHz  | · · · · · · | 2.5  |      | mA   |      |
|                 | • 24 MHz  | _           | 3    | _    | mA   |      |
|                 | • 32 MHz  | _           | 4    | _    | mA   |      |
| Cx              | EXTAL load capacitance  | _           | -    | —    |      | 2, 3 |
| Cy              | XTAL load capacitance   | _           | -    | _    |      | 2, 3 |
| R <sub>F</sub>  | Feedback resistor — low-frequency, low-power mode (HGO=0)     | _           | _    | _    | MΩ   | 2, 4 |
|                 | Feedback resistor — low-frequency, high-gain<br>mode (HGO=1)  | -           | 10   |      | MΩ   |      |
|                 | Feedback resistor — high-frequency, low-power<br>mode (HGO=0) | -           | -    | -    | MΩ   | 1    |
|                 | Feedback resistor — high-frequency, high-gain mode (HGO=1)    | -           | 1    |      | MΩ   |      |
| R <sub>S</sub>  | Series resistor — low-frequency, low-power<br>mode (HGO=0)    | —           | _    | -    | kΩ   |      |
|                 | Series resistor — low-frequency, high-gain mode (HGO=1)       | _           | 200  | -    | kΩ   |      |
|                 | Series resistor — high-frequency, low-power<br>mode (HGO=0)   | -           |      |      | kΩ   |      |
|                 | Series resistor — high-frequency, high-gain mode (HGO=1)      |             |      |      |      |      |
|                 |   | _           | 0    | _    | kΩ   |      |

Table continues on the next page ...

| Symbol                       | Description  | Min. | Тур.            | Max. | Unit | Notes |
|------------------------------|--|------|-----------------|------|------|-------|
| V <sub>pp</sub> <sup>5</sup> | Peak-to-peak amplitude of oscillation (oscillator<br>mode) — low-frequency, low-power mode<br>(HGO=0)  | _    | 0.6             | _    | V    |       |
|                              | Peak-to-peak amplitude of oscillation (oscillator<br>mode) — low-frequency, high-gain mode<br>(HGO=1)  | _    | V <sub>DD</sub> | _    | V    |       |
|                              | Peak-to-peak amplitude of oscillation (oscillator<br>mode) — high-frequency, low-power mode<br>(HGO=0) | _    | 0.6             | _    | V    |       |
|                              | Peak-to-peak amplitude of oscillation (oscillator<br>mode) — high-frequency, high-gain mode<br>(HGO=1) | _    | V <sub>DD</sub> | _    | V    |       |

- 1. V<sub>DD</sub>=3.3 V, Temperature =25 °C
- 2. See crystal or resonator manufacturer's recommendation
- 3. C<sub>x</sub>,C<sub>y</sub> can be provided by using either the integrated capacitors or by using external components.
- 4. When low power mode is selected, R<sub>F</sub> is integrated and must not be attached externally.
- 5. The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other devices.

### 8.6.1.1 Oscillator frequency specification

| Symbol                | Description   | Min.     | Тур. | Max.    | Unit | Notes |
|-----------------------|---|----------|------|---------|------|-------|
| f <sub>osc_lo</sub>   | Oscillator crystal or resonator frequency — low<br>frequency mode (MCG_C2[RANGE]=00)                  | 32       | —    | 40      | kHz  |       |
| f <sub>osc_hi_1</sub> | Oscillator crystal or resonator frequency — high<br>frequency mode (low range)<br>(MCG_C2[RANGE]=01)  | 3        | -    | 8       | MHz  |       |
| f <sub>osc_hi_2</sub> | Oscillator crystal or resonator frequency — high<br>frequency mode (high range)<br>(MCG_C2[RANGE]=1x) | 8        | -    | 32      | MHz  |       |
| f <sub>ec_extal</sub> | Input clock frequency (external clock mode)   | _        | -    | 50      | MHz  | 1, 2  |
| t <sub>dc_extal</sub> | Input clock duty cycle (external clock mode)  | 40       | 50   | 60      | %    |       |
| t <sub>cst</sub>      | Crystal startup time — 32 kHz low-frequency,<br>low-power mode (HGO=0)                                | -        | 750  | -       | ms   | 3, 4  |
|                       | Crystal startup time — 32 kHz low-frequency,<br>high-gain mode (HGO=1)                                | <u> </u> | 250  | · · · · | ms   | 1     |
|                       | Crystal startup time — 8 MHz high-frequency<br>(MCG_C2[RANGE]=01), low-power mode<br>(HGO=0)          | -        | 0.6  | -       | ms   |       |
|                       | Crystal startup time — 8 MHz high-frequency<br>(MCG_C2[RANGE]=01), high-gain mode<br>(HGO=1)          |          | 1    | -       | ms   |       |

1. Other frequency limits may apply when external clock is being used as a reference for the FLL or PLL.

 When transitioning from FBE to FEI mode, restrict the frequency of the input clock so that, when it is divided by FRDIV, it remains within the limits of the DCO input clock frequency.

- 3. Proper PC board layout procedures must be followed to achieve specifications.
- Crystal startup time is defined as the time between the oscillator being enabled and the OSCINIT bit in the MCG\_S register being set.

# 8.6.2 32 kHz oscillator electrical characteristics

### 8.6.2.1 32 kHz oscillator DC electrical specifications

| Symbol                       | Description                                   | Min. | Тур. | Max. | Unit |
|------------------------------|---|------|------|------|------|
| V <sub>BAT</sub>             | Supply voltage                                | 1.71 | _    | 3.6  | V    |
| R <sub>F</sub>               | Internal feedback resistor                    | _    | 100  | _    | MΩ   |
| C <sub>para</sub>            | Parasitical capacitance of EXTAL32 and XTAL32 | _    | 5    | 7    | pF   |
| V <sub>pp</sub> <sup>1</sup> | Peak-to-peak amplitude of oscillation         | —    | 0.6  | —    | V    |

 When a crystal is being used with the 32 kHz oscillator, the EXTAL32 and XTAL32 pins should only be connected to required oscillator components and must not be connected to any other devices.

## 8.6.2.2 32 kHz oscillator frequency specifications

| Symbol              | Description                               | Min. | Тур.   | Max. | Unit | Notes |
|---------------------|---|------|--------|------|------|-------|
| f <sub>osc_lo</sub> | Oscillator crystal                        | _    | 32.768 | —    | kHz  |       |
| t <sub>start</sub>  | Crystal start-up time                     | -    | 1000   | —    | ms   | 1     |
| fec_extal32         | Externally provided input clock frequency | -    | 32.768 | —    | kHz  | 2     |
| Vec_extal32         | Externally provided input clock amplitude | 700  | -      | VBAT | mV   | 2, 3  |

1. Proper PC board layout procedures must be followed to achieve specifications.

- This specification is for an externally supplied clock driven to EXTAL32 and does not apply to any other clock input. The oscillator remains enabled and XTAL32 must be left unconnected.
- The parameter specified is a peak-to-peak value and V<sub>IH</sub> and V<sub>IL</sub> specifications do not apply. The voltage of the applied clock must be within the range of V<sub>SS</sub> to V<sub>BAT</sub>.

# 8.7 Memories and memory interfaces

## 8.7.1 Flash electrical specifications

### 8.7.1.1 Flash timing specifications — program and erase

The following specifications represent the amount of time the internal charge pumps are active and do not include command overhead.

| NVM program/erase | timing | specifications |
|-------------------|--------|----------------|
|-------------------|--------|----------------|

| Symbol              | Description                        | Min.         | Тур. | Max. | Unit | Notes |
|---------------------|------------------------------------|--------------|------|------|------|-------|
| t <sub>hvpgm4</sub> | Longword Program high-voltage time | —            | 7.5  | 18   | μs   |       |
| thversscr           | Sector Erase high-voltage time     | 2 <u>—</u> 2 | 13   | 113  | ms   | 1     |

1. Maximum time based on expectations at cycling end-of-life.

# 8.7.1.2 Flash timing specifications — commands

| Symbol                  | Description                                   | Min. | Тур. | Max. | Unit | Notes |
|-------------------------|---|------|------|------|------|-------|
|                         | Read 1s Block execution time                  |      |      |      |      |       |
| trd1blk256k             | 256 KB program/data flash                     | -    | -    | 1.7  | ms   |       |
| t <sub>rd1sec2k</sub>   | Read 1s Section execution time (flash sector) | -    | -    | 60   | μs   | 1     |
| tpgmchk                 | Program Check execution time                  | _    | -    | 45   | μs   | 1     |
| trdrsrc                 | Read Resource execution time                  |      | -    | 30   | μs   | 1     |
| t <sub>pgm4</sub>       | Program Longword execution time               | _    | 65   | 145  | μs   |       |
|                         | Erase Flash Block execution time              |      |      |      |      | 2     |
| t <sub>ersblk256k</sub> | 256 KB program/data flash                     | _    | 122  | 985  | ms   |       |
| tersscr                 | Erase Flash Sector execution time             |      | 14   | 114  | ms   | 2     |
|                         | Program Section execution time                |      |      |      |      |       |
| tpgmsec512              | <ul> <li>512 B flash</li> </ul>               | -    | 2.4  | -    | ms   |       |
| tpgmsec1k               | 1 KB flash                                    | -    | 4.7  | -    | ms   |       |
| tpgmsec2k               | • 2 KB flash                                  |      | 9.3  | -    | ms   |       |
| trd1all                 | Read 1s All Blocks execution time             |      |      | 1.8  | ms   |       |
| trdonce                 | Read Once execution time                      |      | —    | 25   | μs   | 1     |
| tpgmonce                | Program Once execution time                   | -    | 65   | -    | μs   |       |
| t <sub>ersall</sub>     | Erase All Blocks execution time               |      | 250  | 2000 | ms   | 2     |
| t <sub>vfykey</sub>     | Verify Backdoor Access Key execution time     | -    |      | 30   | μs   | 1     |
|                         | Swap Control execution time                   |      |      |      |      |       |
| t <sub>swapx01</sub>    | control code 0x01                             | _    | 200  |      | μs   |       |
| t <sub>swapx02</sub>    | control code 0x02                             | -    | 70   | 150  | μs   |       |
| t <sub>swapx04</sub>    | control code 0x04                             | -    | 70   | 150  | μs   |       |
| t <sub>swapx08</sub>    | control code 0x08                             | -    |      | 30   | μs   |       |

Table continues on the next page ...

| Symbol                   | Description   | Min.       | Тур.         | Max. | Unit | Notes |
|--------------------------|---|------------|--------------|------|------|-------|
|                          | Program Partition for EEPROM execution time                 |            |              |      |      |       |
| tpgmpart64k              | 256 KB FlexNVM  |            | 145          | —    | ms   |       |
| tpgmpart256k             |   |            |              |      |      |       |
|                          | Set FlexRAM Function execution time:                        |            |              |      |      |       |
| tsetramff                | Control Code 0xFF   | —          | 70           | _    | μs   |       |
| t <sub>setram32k</sub>   | <ul> <li>32 KB EEPROM backup</li> </ul>                     |            | 0.8          | 1.2  | ms   |       |
| t <sub>setram64k</sub>   | 64 KB EEPROM backup   |            | 1.3          | 1.9  | ms   |       |
| t <sub>setram256k</sub>  | 256 KB EEPROM backup  | _          | 4.5          | 5.5  | ms   |       |
|                          | Byte-write to FlexRAM                                       | for EEPROM | operation    |      |      |       |
| t <sub>eewr8bers</sub>   | Byte-write to erased FlexRAM location execution time        | -          | 175          | 260  | μs   | 3     |
|                          | Byte-write to FlexRAM execution time:                       |            |              |      |      |       |
| teewr8b32k               | <ul> <li>32 KB EEPROM backup</li> </ul>                     | —          | 385          | 1800 | μs   |       |
| teewr8b64k               | <ul> <li>64 KB EEPROM backup</li> </ul>                     |            | 475          | 2000 | μs   |       |
| teewr8b128k              | <ul> <li>128 KB EEPROM backup</li> </ul>                    | _          | 650          | 2400 | μs   |       |
| t <sub>eewr8b256k</sub>  | 256 KB EEPROM backup  | -          | 1000         | 3200 | μs   |       |
|                          | Word-write to FlexRAM                                       | for EEPRON | l operation  |      |      |       |
| t <sub>eewr16bers</sub>  | Word-write to erased FlexRAM location<br>execution time     | -          | 175          | 260  | μs   |       |
|                          | Word-write to FlexRAM execution time:                       |            |              |      |      |       |
| t <sub>eewr16b32k</sub>  | <ul> <li>32 KB EEPROM backup</li> </ul>                     | —          | 385          | 1800 | μs   |       |
| t <sub>eewr16b64k</sub>  | <ul> <li>64 KB EEPROM backup</li> </ul>                     | -          | 475          | 2000 | μs   |       |
| teewr16b128k             | <ul> <li>128 KB EEPROM backup</li> </ul>                    | -          | 650          | 2400 | μs   |       |
| t <sub>eewr16b256k</sub> | 256 KB EEPROM backup  | —          | 1000         | 3200 | μs   |       |
|                          | Longword-write to FlexRA                                    | M for EEPR | OM operation | 1    |      |       |
| t <sub>eewr32bers</sub>  | Longword-write to erased FlexRAM location<br>execution time | _          | 360          | 540  | μs   |       |
|                          | Longword-write to FlexRAM execution time:                   |            |              |      |      |       |
| t <sub>eewr32b32k</sub>  | <ul> <li>32 KB EEPROM backup</li> </ul>                     | _          | 630          | 2050 | μs   |       |
| t <sub>eewr32b64k</sub>  | <ul> <li>64 KB EEPROM backup</li> </ul>                     | —          | 810          | 2250 | μs   |       |
| t <sub>eewr32b128k</sub> | <ul> <li>128 KB EEPROM backup</li> </ul>                    |            | 1200         | 2675 | μs   |       |
| t <sub>eewr32b256k</sub> | 256 KB EEPROM backup  | -          | 1900         | 3500 | μs   |       |

Assumes 25MHz flash clock frequency.
 Maximum times for erase parameters based on expectations at cycling end-of-life.

3. For byte-writes to an erased FlexRAM location, the aligned word containing the byte must be erased.

## 8.7.1.3 Flash high voltage current behaviors

| Symbol              | Description  | Min. | Тур. | Max. | Unit |
|---------------------|--|------|------|------|------|
| I <sub>DD_PGM</sub> | Average current adder during high voltage<br>flash programming operation | —    | 2.5  | 6.0  | mA   |
| I <sub>DD_ERS</sub> | Average current adder during high voltage<br>flash erase operation       | —    | 1.5  | 4.0  | mA   |

## 8.7.1.4 NVM reliability specifications

| Symbol                   | Description   | Min.    | Typ. <sup>1</sup> | Max. | Unit   | Notes |
|--------------------------|---|---------|-------------------|------|--------|-------|
|                          | Program   | n Flash |                   |      |        |       |
| t <sub>nvmretp10k</sub>  | Data retention after up to 10 K cycles                          | 5       | 50                | _    | years  |       |
| t <sub>nvmretp1k</sub>   | Data retention after up to 1 K cycles                           | 20      | 100               | -    | years  |       |
| n <sub>nvmcycp</sub>     | Cycling endurance   | 10 K    | 50 K              | -    | cycles | 2     |
|                          | Data  | Flash   |                   |      |        |       |
| t <sub>nvmretd10k</sub>  | Data retention after up to 10 K cycles                          | 5       | 50                | -    | years  |       |
| t <sub>nvmretd1k</sub>   | Data retention after up to 1 K cycles                           | 20      | 100               | _    | years  |       |
| n <sub>nvmcycd</sub>     | Cycling endurance   | 10 K    | 50 K              | _    | cycles | 2     |
|                          | FlexRAM as  | EEPROM  |                   |      |        |       |
| t <sub>nvmretee100</sub> | Data retention up to 100% of write endurance                    | 5       | 50                |      | years  |       |
| t <sub>nvmretee10</sub>  | Data retention up to 10% of write endurance                     | 20      | 100               | -    | years  |       |
|                          | Write endurance   |         |                   |      |        | 3     |
| n <sub>nvmwree16</sub>   | EEPROM backup to FlexRAM ratio = 16                             | 35 K    | 175 K             | _    | writes |       |
| n <sub>nvmwree128</sub>  | EEPROM backup to FlexRAM ratio = 128                            | 315 K   | 1.6 M             | -    | writes |       |
| n <sub>nvmwree512</sub>  | EEPROM backup to FlexRAM ratio = 512                            | 1.27 M  | 6.4 M             | _    | writes |       |
| n <sub>nymwree4k</sub>   | EEPROM backup to FlexRAM ratio = 4096                           | 10 M    | 50 M              | —    | writes |       |
| N <sub>nvmwree32k</sub>  | <ul> <li>EEPROM backup to FlexRAM ratio =<br/>32,768</li> </ul> | 80 M    | 400 M             | —    | writes |       |

 Typical data retention values are based on measured response accelerated at high temperature and derated to a constant 25°C use profile. Engineering Bulletin EB618 does not apply to this technology. Typical endurance defined in Engineering Bulletin EB619.

2. Cycling endurance represents number of program/erase cycles at -40°C  $\leq$  T<sub>j</sub>  $\leq$  125°C.

 Write endurance represents the number of writes to each FlexRAM location at -40°C ≤Tj ≤ 125°C influenced by the cycling endurance of the FlexNVM (same value as data flash) and the allocated EEPROM backup per subsystem. Minimum and typical values assume all byte-writes to FlexRAM.

## 8.7.1.5 Write endurance to FlexRAM for EEPROM

When the FlexNVM partition code is not set to full data flash, the EEPROM data set size can be set to any of several non-zero values.

The bytes not assigned to data flash via the FlexNVM partition code are used by the flash memory module to obtain an effective endurance increase for the EEPROM data. The built-in EEPROM record management system raises the number of program/erase cycles that can be attained prior to device wear-out by cycling the EEPROM data through a larger EEPROM NVM storage space.

While different partitions of the FlexNVM are available, the intention is that a single choice for the FlexNVM partition code and EEPROM data set size is used throughout the entire lifetime of a given application. The EEPROM endurance equation and graph shown below assume that only one configuration is ever used.

# Writes\_subsystem = EEESPLIT Å~ EEESIZE x Write\_efficiency x n<sub>nvmcycd</sub>

### where

- Writes\_subsystem minimum number of writes to each FlexRAM location for subsystem (each subsystem can have different endurance)
- EEPROM allocated FlexNVM for each EEPROM subsystem based on DEPART; entered with the Program Partition command
- EEESPLIT FlexRAM split factor for subsystem; entered with the Program Partition command
- EEESIZE allocated FlexRAM based on DEPART; entered with the Program Partition command
- Write\_efficiency
  - 0.25 for 8-bit writes to FlexRAM
  - 0.50 for 16-bit or 32-bit writes to FlexRAM
- nn<sub>vmcvcd</sub> data flash cycling endurance (the following graph assumes 10,000 cycles)

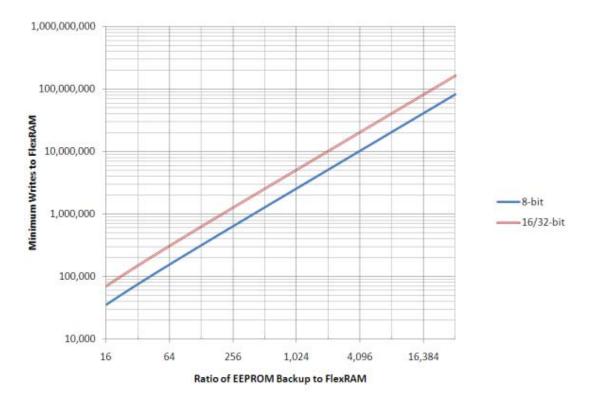
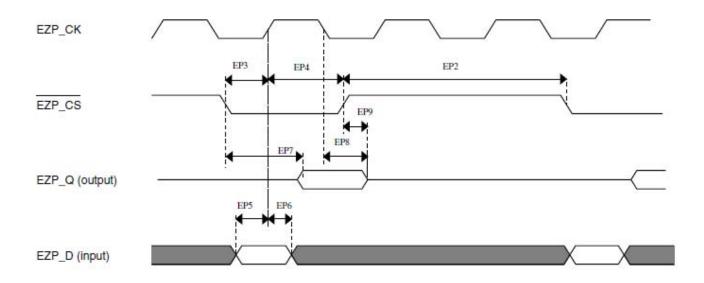
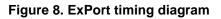


Figure 7. EEPROM backup writes to FlexRAM

# 8.7.2 EzPort switching specifications

| Num  | Description  | Min.                    | Max.                | Unit |
|------|--|-------------------------|---------------------|------|
|      | Operating voltage  | 1.71                    | 3.6                 | V    |
| EP1  | EZP_CK frequency of operation (all commands except READ) | -                       | fsys/2              | MHz  |
| EP1a | EZP_CK frequency of operation (READ command)             | -                       | f <sub>SYS</sub> /8 | MHz  |
| EP2  | EZP_CS negation to next EZP_CS assertion                 | 2 x t <sub>EZP_CK</sub> | 19 <u>47 -</u> 34   | ns   |
| EP3  | EZP_CS input valid to EZP_CK high (setup)                | 5                       | 11 <u></u> 11       | ns   |
| EP4  | EZP_CK high to EZP_CS input invalid (hold)               | 5                       | _                   | ns   |
| EP5  | EZP_D input valid to EZP_CK high (setup)                 | 2                       | 8                   | ns   |
| EP6  | EZP_CK high to EZP_D input invalid (hold)                | 5                       | _                   | ns   |
| EP7  | EZP_CK low to EZP_Q output valid                         | _                       |                     | ns   |
| EP8  | EZP_CK low to EZP_Q output invalid (hold)                | 0                       |                     | ns   |
| EP9  | EZP_CS negation to EZP_Q tri-state                       | _                       | 12                  | ns   |





# 8.8 Analog

## 8.8.1 ADC electrical specifications

The 16-bit accuracy specifications are achievable on the differential pins ADCx\_DP0, ADCx\_DM0. All other ADC channels meet the 13-bit differential/12-bit single-ended accuracy specifications.

| Symbol            | Description    | Conditions  | Min. | Typ. <sup>1</sup> | Max. | Unit | Notes |
|-------------------|----------------|---|------|-------------------|------|------|-------|
| VDDA              | Supply voltage | Absolute  | 1.71 | —                 | 3.6  | V    |       |
| ΔV <sub>DDA</sub> | Supply voltage | Delta to V <sub>DD</sub> (V <sub>DD</sub> -V <sub>DDA</sub> ) | -100 | 0                 | +100 | mV   | 2     |
| $\Delta V_{SSA}$  | Ground voltage | Delta to V <sub>SS</sub> (V <sub>SS</sub> -V <sub>SSA</sub> ) | -100 | 0                 | +100 | mV   | 2     |

| Symbol            | Description                       | Conditions   | Min.              | Typ. <sup>1</sup> | Max.              | Unit | Notes |
|-------------------|-----------------------------------|--|-------------------|-------------------|-------------------|------|-------|
| V <sub>REFH</sub> | ADC reference<br>voltage high     |  | 1.13              | V <sub>DDA</sub>  | V <sub>DDA</sub>  | V    |       |
| V <sub>REFL</sub> | Reference<br>voltage low          |  | V <sub>SSA</sub>  | V <sub>SSA</sub>  | V <sub>SSA</sub>  | v    |       |
| V <sub>ADIN</sub> | Input voltage                     |  | V <sub>REFL</sub> | _                 | V <sub>REFH</sub> | V    |       |
| CADIN             | Input capacitance                 | <ul> <li>16 bit modes</li> </ul>                                 | _                 | 8                 | 10                | pF   |       |
|                   |                                   | <ul> <li>8/10/12 bit modes</li> </ul>                            | —                 | 4                 | 5                 |      |       |
| R <sub>ADIN</sub> | Input resistance                  |  | _                 | 2                 | 5                 | kΩ   |       |
| R <sub>AS</sub>   | Analog source                     | 13/12 bit modes  |                   |                   |                   |      | 3     |
|                   | resistance                        | f <sub>ADCK</sub> < 4MHz   | _                 | _                 | 5                 | kΩ   |       |
| f <sub>ADCK</sub> | ADC conversion<br>clock frequency | ≤ 13 bit modes   |                   |                   |                   |      | 4     |
|                   | clock frequency                   |  | 1.0               | _                 | 18.0              | MHz  |       |
| f <sub>ADCK</sub> | ADC conversion<br>clock frequency | 16 bit modes   |                   |                   |                   |      | 4     |
|                   |                                   |  | 2.0               | _                 | 12.0              | MHz  |       |
| Crate             | ADC conversion<br>rate            | ≤ 13 bit modes   |                   |                   |                   |      | 5     |
|                   | Tale                              | No ADC hardware averaging  | 20.000            | _                 | 818.330           | Ksps |       |
|                   |                                   | Continuous conversions<br>enabled, subsequent<br>conversion time |                   |                   |                   |      |       |
| Crate             | ADC conversion                    | 16 bit modes   |                   |                   |                   |      | 5     |
|                   | rate                              | No ADC hardware averaging  | 37.037            | _                 | 461.467           | Ksps |       |
|                   |                                   | Continuous conversions<br>enabled, subsequent<br>conversion time |                   |                   |                   |      |       |

- Typical values assume V<sub>DDA</sub> = 3.0 V, Temp = 25°C, f<sub>ADCK</sub> = 1.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
- 2. DC potential difference.
- This resistance is external to MCU. The analog source resistance should be kept as low as possible in order to achieve the best results. The results in this datasheet were derived from a system which has <8 Ω analog source resistance. The R<sub>AS</sub>/ C<sub>AS</sub> time constant should be kept to <1ns.</li>
- 4. To use the maximum ADC conversion clock frequency, the ADHSC bit should be set and the ADLPC bit should be clear.
- For guidelines and examples of conversion rate calculation, download the ADC calculator tool: http://cache.freescale.com/ files/soft\_dev\_tools/software/app\_software/converters/ADC\_CALCULATOR\_CNV.zip?fpsp=1

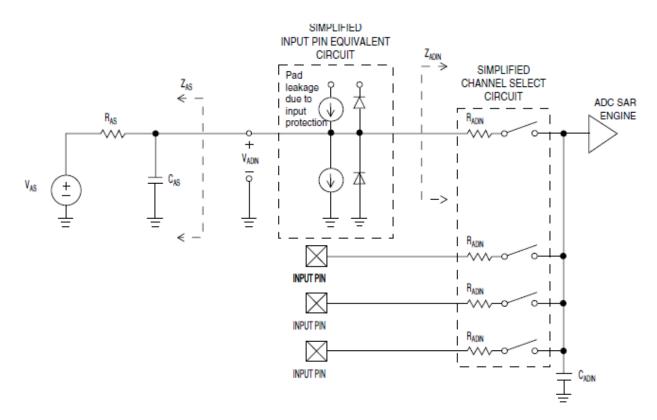


Figure 9. ADC input impedance equivalency diagram

## 8.8.1.1 16-bit ADC electrical characteristics

| Symbol          | Description                  | Conditions <sup>1</sup>              | Min.           | Typ. <sup>2</sup> | Max.         | Unit             | Notes               |
|-----------------|------------------------------|--------------------------------------|----------------|-------------------|--------------|------------------|---------------------|
| IDDA_ADC        | Supply current               |                                      | 0.215          | —                 | 1.7          | mA               | 3                   |
|                 | ADC                          | <ul> <li>ADLPC=1, ADHSC=0</li> </ul> | 1.2            | 2.4               | 3.9          | MHz              | tADACK = 1          |
|                 | asynchronous<br>clock source | <ul> <li>ADLPC=1, ADHSC=1</li> </ul> | 3.0            | 4.0               | 7.3          | MHz              | <b>f</b> ADACK      |
| <b>f</b> ADACK  | check course                 | <ul> <li>ADLPC=0, ADHSC=0</li> </ul> | 2.4            | 5.2               | 6.1          | MHz              |                     |
|                 |                              | <ul> <li>ADLPC=0, ADHSC=1</li> </ul> | 4.4            | 6.2               | 9.5          | MHz              |                     |
|                 | Sample Time                  | See Reference Manual chapte          | r for sample t | times             |              |                  |                     |
| TUE             | Total unadjusted             | 12 bit modes                         |                | ±4                | ±6.8         | LSB <sup>4</sup> | 5                   |
|                 | error                        | <li>&lt;12 bit modes</li>            | -              | ±1.4              | ±2.1         |                  |                     |
| DNL             | Differential non-            | 12 bit modes                         |                | ±0.7              | -1.1 to +1.9 | LSB <sup>4</sup> | 5                   |
|                 | linearity                    |                                      |                |                   | -0.3 to 0.5  |                  |                     |
|                 |                              | 12 bit modes                         | <u></u> 0      | ±0.2              |              |                  |                     |
| INL             | Integral non-                | 12 bit modes                         |                | ±1.0              | -2.7 to +1.9 | LSB <sup>4</sup> | 5                   |
|                 | linearity                    |                                      |                |                   | -0.7 to +0.5 |                  |                     |
|                 |                              | 12 bit modes                         | _              | ±0.5              |              |                  |                     |
| E <sub>FS</sub> | Full-scale error             | 12 bit modes                         |                | -4                | -5.4         | LSB <sup>4</sup> | V <sub>ADIN</sub> = |
|                 |                              | 12 bit modes                         |                | -1.4              | -1.8         |                  | VDDA                |
|                 |                              |                                      |                |                   |              |                  | 5                   |

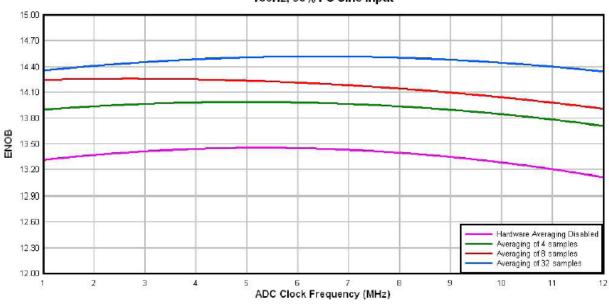
Table continues on the next page ...

| Symbol              | Description                        | Conditions <sup>1</sup>           | Min.     | Typ. <sup>2</sup>      | Max. | Unit             | Notes  |
|---------------------|------------------------------------|-----------------------------------|----------|------------------------|------|------------------|--|
| EQ                  | Quantization                       | <ul> <li>16 bit modes</li> </ul>  | -        | -1 to 0                | _    | LSB <sup>4</sup> |  |
|                     | error                              | <ul> <li>≤13 bit modes</li> </ul> | -        | -                      | ±0.5 | 1.00100          |  |
| ENOB                | Effective number                   | 16 bit differential mode          |          |                        |      |                  | 6  |
|                     | of bits                            | <ul> <li>Avg=32</li> </ul>        | 12.8     | 14.5                   | _    | bits             |  |
|                     |                                    | • Avg=4                           | 11.9     | 13.8                   | _    | bits             |  |
|                     |                                    | 16 bit single-ended mode          |          |                        |      |                  |  |
|                     |                                    | • Avg=32                          | 12.2     | 13.9                   | _    | bits             |  |
|                     |                                    | • Avg=4                           | 11.4     | 13.1                   | _    | bits             |  |
| SINAD               | Signal-to-noise<br>plus distortion | See ENOB                          | 6.02     | 2 × ENOB +             | 1.76 | dB               |  |
| THD                 | Total harmonic                     | 16 bit differential mode          |          |                        |      |                  | 7  |
|                     | distortion                         | • Avg=32                          | -        | -94                    | -    | dB               |  |
|                     |                                    | 16 bit single-ended mode          | -        | -85                    | _    | dB               |  |
|                     |                                    | <ul> <li>Avg=32</li> </ul>        |          |                        |      |                  |  |
| SFDR                | Spurious free                      | 16 bit differential mode          |          |                        |      |                  | 7  |
|                     | dynamic range                      | • Avg=32                          | 82       | 95                     | -    | dB               |  |
|                     |                                    | 16 bit single-ended mode          | 78       | 90                     | _    | dB               |  |
|                     |                                    | • Avg=32                          |          |                        |      |                  |  |
| EIL                 | Input leakage<br>error             |                                   |          | $I_{ln} \times R_{AS}$ |      | mV               | I <sub>In</sub> =<br>Ieakage<br>current                                  |
|                     |                                    |                                   |          |                        |      |                  | (refer to<br>the MCU's<br>voltage<br>and curren<br>operating<br>ratings) |
|                     | Temp sensor<br>slope               | -40°C to 105°C                    | -        | 1.715                  | -    | mV/°C            |  |
| V <sub>TEMP25</sub> | Temp sensor<br>voltage             | 25°C                              | <u> </u> | 719                    |      | mV               |  |

1. All accuracy numbers assume the ADC is calibrated with  $V_{REFH} = V_{DDA}$ 

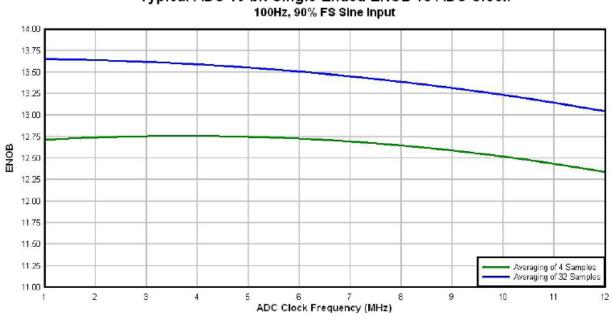
 Typical values assume V<sub>DDA</sub> = 3.0 V, Temp = 25°C, f<sub>ADCK</sub> = 2.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.

- The ADC supply current depends on the ADC conversion clock speed, conversion rate and the ADLPC bit (low power). For lowest power operation the ADLPC bit should be set, the HSC bit should be clear with 1MHz ADC conversion clock speed.
- 4. 1 LSB =  $(V_{REFH} V_{REFL})/2^N$
- 5. ADC conversion clock <16MHz, Max hardware averaging (AVGE = %1, AVGS = %11)
- 6. Input data is 100 Hz sine wave. ADC conversion clock <12MHz.
- 7. Input data is 1 kHz sine wave. ADC conversion clock <12MHz.



Typical ADC 16-bit Differential ENOB vs ADC Clock 100Hz, 90% FS Sine Input





Typical ADC 16-bit Single-Ended ENOB vs ADC Clock

Figure 11. Typical ENOB vs. ADC\_CLK for 16-bit single-ended mode

# 8.8.2 CMP and 6-bit DAC electrical specifications

| Symbol           | Description   | Min.                  | Тур. | Max.            | Unit             |
|------------------|---|-----------------------|------|-----------------|------------------|
| V <sub>DD</sub>  | Supply voltage                                      | 1.71                  | -    | 3.6             | V                |
| IDDHS            | Supply current, High-speed mode (EN=1, PMODE=1)     |                       | -    | 200             | μA               |
| IDDLS            | Supply current, low-speed mode (EN=1, PMODE=0)      | -                     | -    | 20              | μA               |
| VAIN             | Analog input voltage                                | V <sub>SS</sub> - 0.3 | -    | V <sub>DD</sub> | V                |
| VAIO             | Analog input offset voltage                         | -                     | -    | 20              | mV               |
| V <sub>H</sub>   | Analog comparator hysteresis <sup>1</sup>           |                       |      |                 |                  |
|                  | <ul> <li>CR0[HYSTCTR] = 00</li> </ul>               | -                     | 5    | -               | mV               |
|                  | <ul> <li>CR0[HYSTCTR] = 01</li> </ul>               |                       | 10   | -               | mV               |
|                  | <ul> <li>CR0[HYSTCTR] = 10</li> </ul>               | -                     | 20   | _               | mV               |
|                  | <ul> <li>CR0[HYSTCTR] = 11</li> </ul>               | 2                     | 30   | -               | mV               |
| VCMPOh           | Output high   | V <sub>DD</sub> – 0.5 |      | -               | V                |
| VCMPOI           | Output low  | -                     | _    | 0.5             | V                |
| t <sub>DHS</sub> | Propagation delay, high-speed mode (EN=1, PMODE=1)  | 20                    | 50   | 200             | ns               |
| t <sub>DLS</sub> | Propagation delay, low-speed mode (EN=1, PMODE=0)   | 80                    | 250  | 600             | ns               |
|                  | Analog comparator initialization delay <sup>2</sup> |                       |      | 40              | μs               |
| IDAC6b           | 6-bit DAC current adder (enabled)                   | -                     | 7    | -               | μA               |
| INL              | 6-bit DAC integral non-linearity                    | -0.5                  | -    | 0.5             | LSB <sup>3</sup> |
| DNL              | 6-bit DAC differential non-linearity                | -0.3                  |      | 0.3             | LSB              |

1. Typical hysteresis is measured with input voltage range limited to 0.6 to V<sub>DD</sub>-0.6V.

2. Comparator initialization delay is defined as the time between software writes to change control inputs (Writes to DACEN, VRSEL, PSEL, MSEL, VOSEL) and the comparator output settling to a stable level.

3. 1 LSB = V<sub>reference</sub>/64

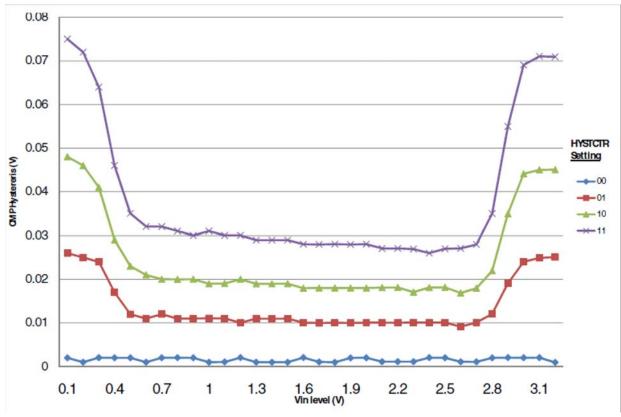
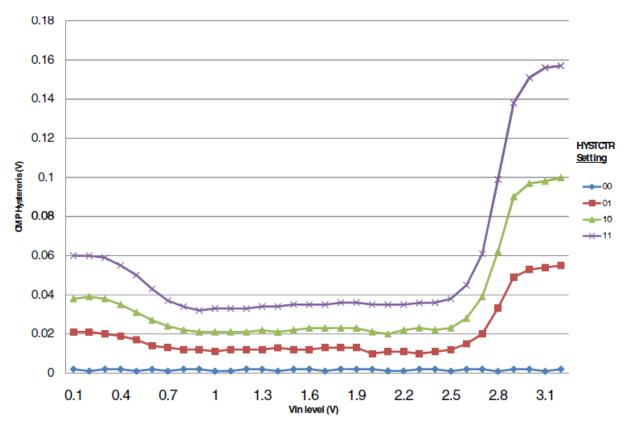
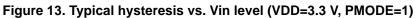


Figure 12. Typical hysteresis vs. Vin level (VDD=3.3 V, PMODE=0)





## 8.8.3 12-bit DAC electrical characteristics

### 8.8.3.1 12-bit DAC operating requirements

| Symbol | Desciption              | Min. | Max. | Unit | Notes |
|--------|-------------------------|------|------|------|-------|
| VDDA   | Supply voltage          | 1.71 | 3.6  | V    |       |
| VDACR  | Reference voltage       | 1.13 | 3.6  | V    | 1     |
| TA     | Temperature             | -40  | 105  | °C   |       |
| CL     | Output load capacitance |      | 100  | pF   | 2     |
| ΙL     | Output load current     |      | 1    | mA   |       |

1. The DAC reference can be selected to be VDDA or the voltage output of the VREF module (VREF\_OUT)

2. A small load capacitance (47 pF) can improve the bandwidth performance of the DAC

## 8.8.3.2 12-bit DAC operating behaviors

The following table contains information about the 12-bit DAC on the MCU.

| Symbol               | Description   | Min.                      | Тур.     | Max.  | Unit   | Notes |
|----------------------|---|---------------------------|----------|-------|--------|-------|
| DDA_DACL             | Supply current — low-power mode   |                           | -        | 150   | μA     |       |
| DDA_DACH             | Supply current — high-speed mode  | -                         |          | 700   | μA     |       |
| t <sub>DACLP</sub>   | Full-scale settling time (0x080 to 0xF7F) —<br>low-power mode                       | _                         | 100      | 200   | μs     | 1     |
| <b>t</b> DACHP       | Full-scale settling time (0x080 to 0xF7F) — high-power mode                         | —                         | 15       | 30    | μs     | 1     |
| t <sub>CCDACLP</sub> | Code-to-code settling time (0xBF8 to 0xC08)<br>— low-power mode and high-speed mode |                           | 0.7      | 1     | μs     | 1     |
| Vdacouti             | DAC output voltage range low — high-speed<br>mode, no load, DAC set to 0x000        |                           | -        | 100   | mV     |       |
| Vdacouth             | DAC output voltage range high — high-<br>speed mode, no load, DAC set to 0xFFF      | V <sub>DACR</sub><br>-100 | -        | VDACR | mV     |       |
| INL                  | Integral non-linearity error — high speed mode                                      | _                         | -        | ±8    | LSB    | 2     |
| DNL                  | Differential non-linearity error — V <sub>DACR</sub> > 2<br>V                       | —                         | -        | ±1    | LSB    | 3     |
| DNL                  | Differential non-linearity error — V <sub>DACR</sub> =<br>VREF_OUT                  | _                         | -        | ±1    | LSB    | 4     |
| VOFFSET              | Offset error  | -                         | ±0.4     | ±0.8  | %FSR   | 5     |
| EG                   | Gain error  |                           | ±0.1     | ±0.6  | %FSR   | 5     |
| PSRR                 | Power supply rejection ratio, V <sub>DDA</sub> > = 2.4 V                            | 60                        | -        | 90    | dB     |       |
| T <sub>CO</sub>      | Temperature coefficient offset voltage  |                           | 3.7      | _     | μV/C   | 6     |
| T <sub>GE</sub>      | Temperature coefficient gain error  | _                         | 0.000421 |       | %FSR/C |       |
| Rop                  | Output resistance load = 3 kΩ   | -                         |          | 250   | Ω      |       |
| SR                   | Slew rate -80h→ F7Fh→ 80h   |                           |          |       | V/µs   |       |
|                      | High power (SP <sub>HP</sub> )  | 1.2                       | 1.7      |       |        |       |
|                      | Low power (SPLP)  | 0.05                      | 0.12     | —     |        |       |
| CT                   | Channel to channel cross talk   | _                         | -        | -80   | dB     | -     |
| BW                   | 3dB bandwidth   |                           |          |       | kHz    |       |
|                      | High power (SP <sub>HP</sub> )  | 550                       | -        | -     |        |       |
|                      | Low power (SPLP)  | 40                        |          | -     |        |       |

1. Settling within ±1 LSB

2. The INL is measured for 0+100mV to  $V_{DACR}$ -100 mV 3. The DNL is measured for 0+100 mV to  $V_{DACR}$ -100 mV

4. The DNL is measured for 0+100mV to  $V_{DACR}\mbox{--}100$  mV with  $V_{DDA}\mbox{--}2.4V$ 

5. Calculated by a best fit curve from V\_{SS}+100 mV to V\_{DACR}-100 mV

6. VDDA = 3.0V, reference select set for VDDA (DACx\_CO:DACRFS = 1), high power mode(DACx\_CO:LPEN = 0), DAC set to 0x800, Temp range from -40C to 105C

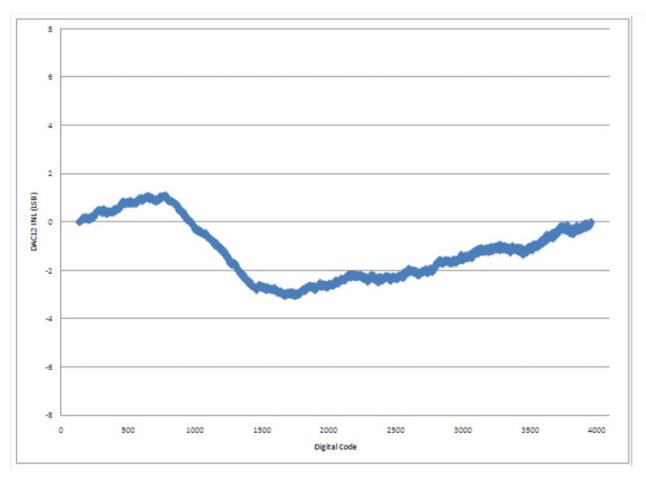


Figure 14. Typical INL error vs. digital code

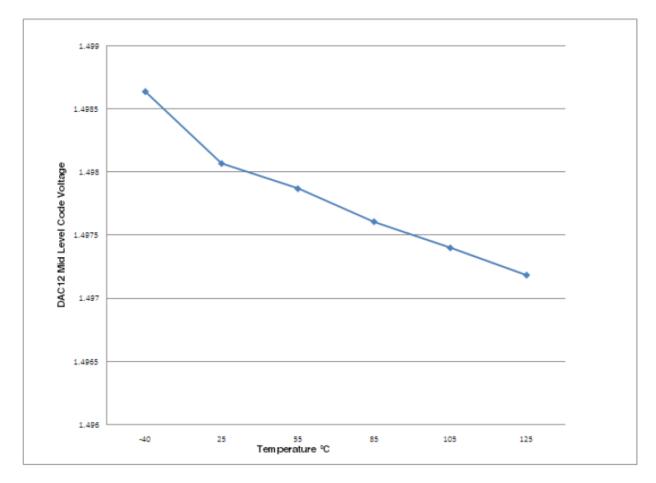


Figure 15. Offset at half scale vs. temperature

# 8.8.4 Voltage reference electrical specifications

### 8.8.4.1 VREF full-range operating requirements

| Symbol | Description             | Min. | Max. | Unit | Notes |
|--------|-------------------------|------|------|------|-------|
| VDDA   | Supply voltage          | 1.71 | 3.6  | V    |       |
| TA     | Temperature             | -40  | 105  | °C   |       |
| CL     | Output load capacitance | 10   | 100  |      | 1, 2  |

 C<sub>L</sub> must be connected to VREF\_OUT if the VREF\_OUT functionality is being used for either an internal or external reference.

 The load capacitance should not exceed +/-25% of the nominal specified C<sub>L</sub> value over the operating temperature range of the device.

## 8.8.4.2 VREF full-range operating behaviors

| Symbol              | Description   | Min.        | Тур.  | Max.   | Unit | Notes |
|---------------------|---|-------------|-------|--------|------|-------|
| Vout                | Voltage reference output with factory trim at<br>nominal V <sub>DDA</sub> and temperature=25C | 1.1915      | 1.195 | 1.1977 | V    |       |
| Vout                | Voltage reference output — factory trim   | 1.1584      | -     | 1.2376 | V    |       |
| Vout                | Voltage reference output — user trim  | 1.193       | _     | 1.197  | V    |       |
| Vstep               | Voltage reference trim step   | <del></del> | 0.5   | -      | mV   |       |
| Vtdrift             | Temperature drift (Vmax -Vmin across the full temperature range)                              |             |       | 80     | mV   |       |
| Ibg                 | Bandgap only current  |             |       | 80     | μA   | 1     |
| ΔV <sub>LOAD</sub>  | Load regulation<br>• current = ± 1.0 mA   | _           | 200   | _      | μV   | 1, 2  |
| Tstup               | Buffer startup time   | 2<br>2022   |       | 100    | μs   |       |
| V <sub>vdrift</sub> | Voltage drift (Vmax -Vmin across the full voltage range)                                      | _           | 2     | -      | mV   | 1     |

1. See the chip's Reference Manual for the appropriate settings of the VREF Status and Control register.

2. Load regulation voltage is the difference between the VREF\_OUT voltage with no load vs. voltage with defined load

## 8.8.4.3 VREF limited-range operating requirements

| Symbol | Description | Min. | Max. | Unit | Notes |
|--------|-------------|------|------|------|-------|
| TA     | Temperature | 0    | 50   | °C   |       |

### 8.8.4.4 VREF limited-range operating behaviors

| Symbol | Description                                | Min.  | Max.  | Unit | Notes |
|--------|--|-------|-------|------|-------|
| Vout   | Voltage reference output with factory trim | 1.173 | 1.225 | V    |       |

# 8.9 Communication interfaces

## 8.9.1 USB electrical specifications

The USB electricals for the USB On-the-Go module conform to the standards documented by the Universal Serial Bus Implementers Forum. For the most up-to-date standards, visit http://www.usb.org.

#### 8.9.2 **USB DCD electrical specifications**

| Symbol               | Description  | Min.  | Тур. | Max. | Unit |
|----------------------|--|-------|------|------|------|
| V <sub>DP_SRC</sub>  | USB_DP source voltage (up to 250 µA)               | 0.5   | —    | 0.7  | V    |
| V <sub>LGC</sub>     | Threshold voltage for logic high                   | 0.8   | _    | 2.0  | V    |
| I <sub>DP_SRC</sub>  | USB_DP source current                              | 7     | 10   | 13   | μA   |
| I <sub>DM_SINK</sub> | USB_DM sink current                                | 50    | 100  | 150  | μA   |
| R <sub>DM_DWN</sub>  | D- pulldown resistance for data pin contact detect | 14.25 | —    | 24.8 | kΩ   |
| V <sub>DAT_REF</sub> | Data detect voltage                                | 0.25  | 0.33 | 0.4  | V    |

#### **VREG electrical specifications** 8.9.3

| Symbol                | Description   | Min. | Typ. <sup>1</sup> | Max. | Unit     | Notes |
|-----------------------|---|------|-------------------|------|----------|-------|
| VREGIN                | Input supply voltage  | 2.7  | -                 | 5.5  | V        |       |
| IDDon                 | Quiescent current — Run mode, load current<br>equal zero, input supply (VREGIN) > 3.6 V                                 | -    | 120               | 186  | μA       |       |
| DDstby                | Quiescent current — Standby mode, load current equal zero   |      | 1.1               | 1.54 | μA       |       |
| I <sub>DDoff</sub>    | Quiescent current — Shutdown mode<br>• VREGIN = 5.0 V and temperature=25C<br>• Across operating voltage and temperature | _    | 650<br>—          | 4    | nA<br>µA |       |
| LOADrun               | Maximum load current — Run mode   | _    | -                 | 120  | mA       |       |
| LOADstby              | Maximum load current — Standby mode   | -    | -                 | 1    | mA       |       |
| VReg33out             | Regulator output voltage — Input supply<br>(VREGIN) > 3.6 V   |      |                   |      |          |       |
|                       | Run mode  | 3    | 3.3               | 3.6  | v        |       |
|                       | Standby mode  | 2.1  | 2.8               | 3.6  | V        |       |
| V <sub>Reg33out</sub> | Regulator output voltage — Input supply<br>(VREGIN) < 3.6 V, pass-through mode  | 2.1  | -                 | 3.6  | V        | 2     |
| COUT                  | External output capacitor   | 1.76 | 2.2               | 8.16 | μF       |       |
| ESR                   | External output capacitor equivalent series resistance  | 1    | _                 | 100  | mΩ       |       |
| LIM                   | Short circuit current   | _    | 290               |      | mA       |       |

Typical values assume VREGIN = 5.0 V, Temp = 25 °C unless otherwise stated.
 Operating in pass-through mode: regulator output voltage equal to the input voltage minus a drop proportional to I<sub>Load</sub>.

# 8.9.4 DSPI switching specifications (limited voltate range)

The DMA Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provide DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

| Num | Description                         | Min.                          | Max.                      | Unit | Notes |
|-----|-------------------------------------|-------------------------------|---------------------------|------|-------|
|     | Operating voltage                   | 2.7                           | 3.6                       | V    |       |
|     | Frequency of operation              |                               | 25                        | MHz  |       |
| DS1 | DSPI_SCK output cycle time          | 2 x t <sub>BUS</sub>          | —                         | ns   |       |
| DS2 | DSPI_SCK output high/low time       | (t <sub>SCK</sub> /2) - 2     | (t <sub>SCK</sub> /2) + 2 | ns   |       |
| DS3 | DSPI_PCSn valid to DSPI_SCK delay   | (t <sub>BUS</sub> x 2) –<br>2 | -                         | ns   | 1     |
| DS4 | DSPI_SCK to DSPI_PCSn invalid delay | (t <sub>BUS</sub> x 2) –<br>2 | -                         | ns   | 2     |
| DS5 | DSPI_SCK to DSPI_SOUT valid         | -                             | 8.5                       | ns   |       |
| DS6 | DSPI_SCK to DSPI_SOUT invalid       | -2                            | -                         | ns   |       |
| DS7 | DSPI_SIN to DSPI_SCK input setup    | 15                            | —                         | ns   |       |
| DS8 | DSPI_SCK to DSPI_SIN input hold     | 0                             | -                         | ns   |       |

Master mode

1. The delay is programmable in SPIx\_CTARn[PSSCK] and SPIx\_CTARn[CSSCK].

2. The delay is programmable in SPIx\_CTARn[PASC] and SPIx\_CTARn[ASC].

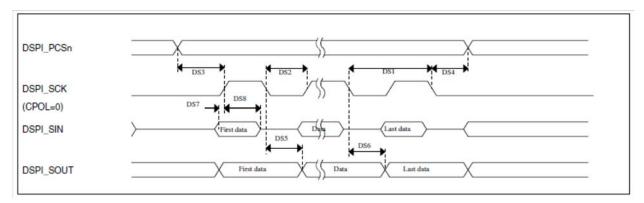


Figure 16. DSPI classic SPI timing — master mode

| Slave | mode |
|-------|------|
|-------|------|

| Num  | Description                              | Min.                      | Max.              | Unit |
|------|--|---------------------------|-------------------|------|
|      | Operating voltage                        | 2.7                       | 3.6               | V    |
|      | Frequency of operation                   |                           | 12.5              | MHz  |
| DS9  | DSPI_SCK input cycle time                | 4 x t <sub>BUS</sub>      | —                 | ns   |
| DS10 | DSPI_SCK input high/low time             | (t <sub>SCK</sub> /2) - 2 | $(t_{SCK}/2) + 2$ | ns   |
| DS11 | DSPI_SCK to DSPI_SOUT valid              | -                         | 10                | ns   |
| DS12 | DSPI_SCK to DSPI_SOUT invalid            | 0                         |                   | ns   |
| DS13 | DSPI_SIN to DSPI_SCK input setup         | 2                         |                   | ns   |
| DS14 | DSPI_SCK to DSPI_SIN input hold          | 7                         |                   | ns   |
| DS15 | DSPI_SS active to DSPI_SOUT driven       | —                         | 14                | ns   |
| DS16 | DSPI_SS inactive to DSPI_SOUT not driven | 10 <del></del> 0          | 14                | ns   |

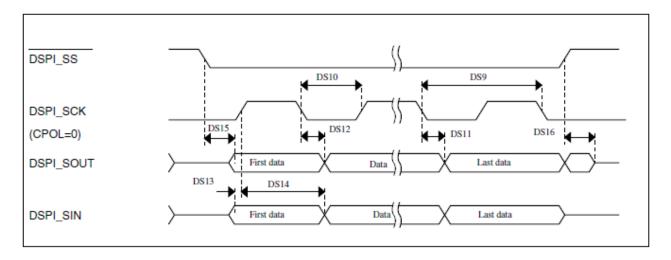


Figure 17. DSPI classic SPI timing — slave mode

# 8.9.5 **DSPI** switching specification (full voltage range)

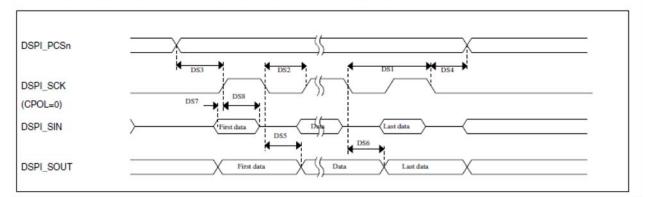
The DMA Serial Peripheral Interface (DSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The tables below provides DSPI timing characteristics for classic SPI timing modes. Refer to the DSPI chapter of the Reference Manual for information on the modified transfer formats used for communicating with slower peripheral devices.

| Num | Description                         | Min.                          | Max.                     | Unit | Notes |
|-----|-------------------------------------|-------------------------------|--------------------------|------|-------|
|     | Operating voltage                   | 1.71                          | 3.6                      | V    | 1     |
|     | Frequency of operation              | ·                             | 12.5                     | MHz  |       |
| DS1 | DSPI_SCK output cycle time          | 4 x t <sub>BUS</sub>          | -                        | ns   |       |
| DS2 | DSPI_SCK output high/low time       | (t <sub>SCK</sub> /2) - 4     | (t <sub>SCK/2)</sub> + 4 | ns   |       |
| DS3 | DSPI_PCSn valid to DSPI_SCK delay   | (t <sub>BUS</sub> x 2) –<br>4 | -                        | ns   | 2     |
| DS4 | DSPI_SCK to DSPI_PCSn invalid delay | (t <sub>BUS</sub> x 2) –<br>4 | _                        | ns   | 3     |
| DS5 | DSPI_SCK to DSPI_SOUT valid         | —                             | 10                       | ns   |       |
| DS6 | DSPI_SCK to DSPI_SOUT invalid       | -4.5                          | 1                        | ns   |       |
| DS7 | DSPI_SIN to DSPI_SCK input setup    | 20.5                          | -                        | ns   |       |
| DS8 | DSPI_SCK to DSPI_SIN input hold     | 0                             | _                        | ns   |       |

#### Master mode DSPI timing (full voltage range)

1. The DSPI module can operate across the entire operating voltage for the processor, but to run across the full voltage range the maximum frequency of operation is reduced.

- 2. The delay is programmable in SPIx\_CTARn[PSSCK] and SPIx\_CTARn[CSSCK].
- 3. The delay is programmable in SPIx\_CTARn[PASC] and SPIx\_CTARn[ASC].



### Figure 18. DSPI classic SPI timing — master mode

#### Slave mode DSPI timing (full voltage range)

| ſ | Num | Description       | Min. | Max. | Unit |
|---|-----|-------------------|------|------|------|
| Γ |     | Operating voltage | 1.71 | 3.6  | V    |

| Num  | Description                             | Min.                      | Max.                     | Unit |
|------|---|---------------------------|--------------------------|------|
|      | Frequency of operation                  | -                         | 6.25                     | MHz  |
| DS9  | DSPI_SCK input cycle time               | 8 x t <sub>BUS</sub>      | 2. <u></u> -2            | ns   |
| DS10 | DSPI_SCK input high/low time            | (t <sub>SCK</sub> /2) - 4 | (t <sub>SCK/2)</sub> + 4 | ns   |
| DS11 | DSPI_SCK to DSPI_SOUT valid             | _                         | 20                       | ns   |
| DS12 | DSPI_SCK to DSPI_SOUT invalid           | 0                         | —                        | ns   |
| DS13 | DSPI_SIN to DSPI_SCK input setup        | 2                         | s <u>—</u> s             | ns   |
| DS14 | DSPI_SCK to DSPI_SIN input hold         | 7                         | s.—                      | ns   |
| DS15 | DSPI_SS active to DSPI_SOUT driven      | 3. <del></del>            | 19                       | ns   |
| DS16 | DSPLSS inactive to DSPL SOUT not driven | 3 <u></u>                 | 19                       | ns   |

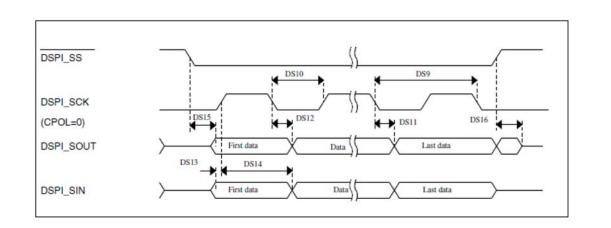


Figure 19. DSPI classic SPI timing — slave mode

# 8.9.6 Normal Run, Wait and Stop mode performance over the fulloperating voltage range

This section provides the operating performance over the full operating voltage for the device in Normal Run, Wait and Stop modes.

| I2S/SAI master m | ode timing |
|------------------|------------|
|------------------|------------|

| Num. | Characteristic  | Min. | Max. | Unit        |
|------|---|------|------|-------------|
|      | Operating voltage   | 1.71 | 3.6  | V           |
| S1   | I2S_MCLK cycle time   | 40   | -    | ns          |
| S2   | I2S_MCLK pulse width high/low                                     | 45%  | 55%  | MCLK period |
| S3   | I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)                       | 80   | -    | ns          |
| S4   | I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low                      | 45%  | 55%  | BCLK period |
| S5   | I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/<br>I2S_RX_FS output valid   | -    | 15   | ns          |
| S6   | I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/<br>I2S_RX_FS output invalid | 0    | -    | ns          |
| S7   | I2S_TX_BCLK to I2S_TXD valid                                      | -    | 15   | ns          |
| S8   | I2S_TX_BCLK to I2S_TXD invalid                                    | 0    | _    | ns          |
| S9   | I2S_RXD/I2S_RX_FS input setup before<br>I2S_RX_BCLK               | 25   |      | ns          |
| S10  | I2S RXD/I2S RX FS input hold after I2S RX BCLK                    | 0    | _    | ns          |

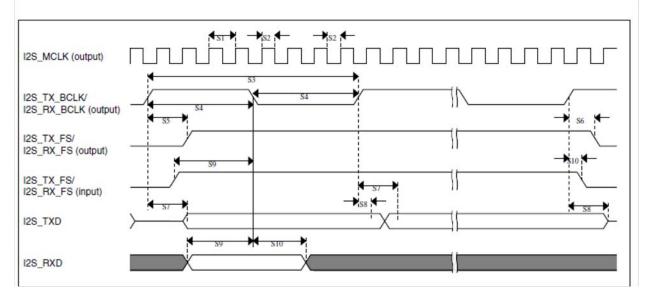


Figure 20. I2S/SAI timing — master modes

| Num. | Characteristic  | Min. | Max. | Unit        |
|------|---|------|------|-------------|
|      | Operating voltage   | 1.71 | 3.6  | V           |
| S11  | I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)                        | 80   | -    | ns          |
| S12  | I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low<br>(input)           | 45%  | 55%  | MCLK period |
| S13  | I2S_TX_FS/I2S_RX_FS input setup before<br>I2S_TX_BCLK/I2S_RX_BCLK | 10   | -    | ns          |
| S14  | I2S_TX_FS/I2S_RX_FS input hold after<br>I2S_TX_BCLK/I2S_RX_BCLK   | 2    | -    | ns          |
| S15  | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid                     | -    | 29   | ns          |
| S16  | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid                   | 0    | -    | ns          |
| S17  | I2S_RXD setup before I2S_RX_BCLK                                  | 10   | —    | ns          |
| S18  | I2S_RXD hold after I2S_RX_BCLK                                    | 2    | -    | ns          |
| S19  | I2S_TX_FS input assertion to I2S_TXD output valid <sup>1</sup>    | -    | 21   | ns          |

#### I2S/SAI slave mode timing

#### 1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

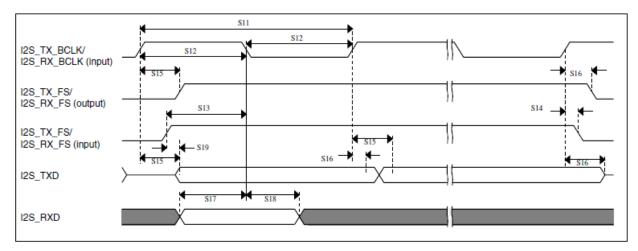


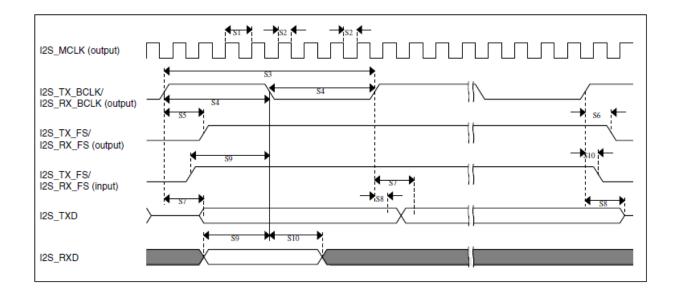
Figure 21. I2S/SAI timing — slave modes

# 8.9.7 VLPR, VLPW, and VLPS mode performance over the full operating voltage range

This section provides the operating performance over the full operating voltage for the device in VLPR, VLPW, and VLPS modes.

| Num. | Characteristic  | Min. | Max. | Unit        |
|------|---|------|------|-------------|
|      | Operating voltage   | 1.71 | 3.6  | V           |
| S1   | I2S_MCLK cycle time   | 62.5 | _    | ns          |
| S2   | I2S_MCLK pulse width high/low                                     | 45%  | 55%  | MCLK period |
| S3   | I2S_TX_BCLK/I2S_RX_BCLK cycle time (output)                       | 250  | _    | ns          |
| S4   | I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low                      | 45%  | 55%  | BCLK period |
| S5   | I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/<br>I2S_RX_FS output valid   | _    | 45   | ns          |
| S6   | I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/<br>I2S_RX_FS output invalid | 0    | -    | ns          |
| S7   | I2S_TX_BCLK to I2S_TXD valid                                      | -    | 45   | ns          |
| S8   | I2S_TX_BCLK to I2S_TXD invalid                                    | 0    | _    | ns          |
| S9   | I2S_RXD/I2S_RX_FS input setup before<br>I2S_RX_BCLK               | 75   | -    | ns          |
| S10  | I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK                    | 0    | _    | ns          |

I2S/SAI master mode timing in VLPR, VLPW, and VLPS modes (full voltage range)



#### Figure 22. I2S/SAI timing — master modes

#### I2S/SAI slave mode timing in VLPR, VLPW, and VLPS modes (full voltage range)

| Num. | Characteristic                                       | Min. | Max. | Unit        |
|------|--|------|------|-------------|
|      | Operating voltage                                    | 1.71 | 3.6  | V           |
| S11  | I2S_TX_BCLK/I2S_RX_BCLK cycle time (input)           | 250  | -    | ns          |
| S12  | I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input) | 45%  | 55%  | MCLK period |

| Num. | Characteristic  | Min. | Max. | Unit |
|------|---|------|------|------|
| S13  | I2S_TX_FS/I2S_RX_FS input setup before<br>I2S_TX_BCLK/I2S_RX_BCLK | 30   | -    | ns   |
| S14  | I2S_TX_FS/I2S_RX_FS input hold after<br>I2S_TX_BCLK/I2S_RX_BCLK   | 2    | -    | ns   |
| S15  | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid                     | -    | 87   | ns   |
| S16  | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid                   | 0    | ·    | ns   |
| S17  | I2S_RXD setup before I2S_RX_BCLK                                  | 30   |      | ns   |
| S18  | I2S_RXD hold after I2S_RX_BCLK                                    | 2    | -    | ns   |
| S19  | I2S_TX_FS input assertion to I2S_TXD output valid1                | -    | 72   | ns   |

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

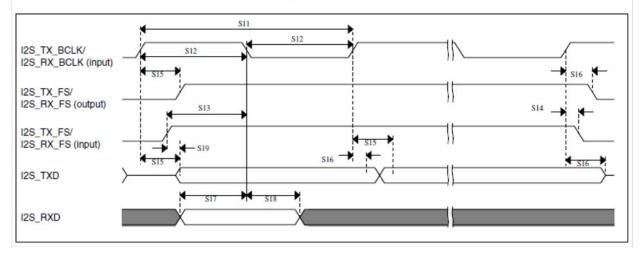


Figure 23. I2S/SAI timing — slave modes

# 9 Transceiver electrical characteristics

# 9.1 DC electrical characteristics

# Table 10. DC electrical characteristics (VBATT, VDDINT = 2.7 V, $T_A$ =25°C, unless otherwise noted)

| Characteristic   | Symbol   | Min      | Тур                                 | Max              | Unit                       |
|--|--|----------|-------------------------------------|------------------|----------------------------|
| Power Supply Current (VBATT + VDDINT)<br>Reset / power down <sup>1</sup><br>Hibernate <sup>1</sup><br>Doze (No CLK_OUT)<br>Idle (No CLK_OUT)<br>Transmit mode (0 dBm nominal output power)<br>Receive mode | I <sub>leakage</sub><br>I <sub>CCH</sub><br>I <sub>CCD</sub><br>I <sub>CCI</sub><br>I <sub>CCT</sub><br>I <sub>CCR</sub> | <br><br> | <30<br><1<br>600<br>700<br>15<br>15 | <br><br>18<br>18 | nA<br>μA<br>μA<br>mA<br>mA |
| Input current (VIN = 0 V or VDDINT) (All digital inputs)   | IIN  | —        | —                                   | ±1               | μA                         |

| Characteristic  | Symbol | Min           | Тур | Max           | Unit |
|---|--------|---------------|-----|---------------|------|
| Input low voltage (all digital inputs)                  | VIL    | 0             | _   | 30%<br>VDDINT | V    |
| Input high voltage (all digital inputs)                 | VIH    | 70%<br>VDDINT | _   | VDDINT        | V    |
| Output high voltage (IOH = -1 mA) (all digital outputs) | VOH    | 80%<br>VDDINT |     | VDDINT        | V    |
| Output low voltage (IOL = 1 mA) (all digital outputs)   | VOL    | 0             |     | 20%<br>VDDINT | V    |

# Table 10. DC electrical characteristics (VBATT, VDDINT = 2.7 V, $T_{\rm A}{=}25^{\circ}{\rm C},$ unless otherwise noted)

<sup>1</sup> To attain specified low power current, all GPIO and other digital IO must be handled properly.

# 9.2 AC electrical characteristics

#### Table 11. Receiver AC electrical characteristics (VBATT, VDDINT=2.7 V, T<sub>A</sub>=25 °C, fref=32 MHz, unless otherwise noted)

| Characteristic  | Symbol  | Min | Тур                        | Max | Unit                       |
|---|---------|-----|----------------------------|-----|----------------------------|
| Sensitivity for 1% packet error rate (PER) (-40 to +105 °C)   | SENSper |     | -99                        | -97 | dBm                        |
| Sensitivity for 1% packet error rate (PER) (+25 °C)   | SENSper |     | -102                       |     | dBm                        |
| Saturation (maximum input level)  | SENSmax |     | +10                        |     | dBm                        |
| Channel rejection for dual port mode (1% PER and desired signal –82 dBm)<br>+5 MHz (adjacent channel)<br>-5 MHz (adjacent channel)<br>+10 MHz (alternate channel)<br>-10 MHz (alternate channel)<br>>= 15 MHz |         |     | 38<br>34<br>47<br>47<br>55 |     | dB<br>dB<br>dB<br>dB<br>dB |
| Frequency error tolerance   |         | _   | —                          | 200 | kHz                        |
| Symbol rate error tolerance   |         | 80  |                            | _   | ppm                        |

# Table 12. Transmitter AC electrical characteristics (VBATT, VDDINT=2.7 V, $T_A$ =25°C, fref=32 MHz, unless otherwise noted)

| Characteristic  | Symbol | Min  | Тур  | Max  | Unit |
|---|--------|------|------|------|------|
| Power spectral density <sup>1</sup> , absolute limit from –40°C to +105°C |        | -30  | _    |      | dBm  |
| Power Spectral Density <sup>2</sup> , Relative limit from –40°C to +105°C |        | -20  | —    | —    | dB   |
| Nominal output power  | Pout   | -0.5 | 0    | 0.5  | dBm  |
| Maximum output power  |        | —    | 10   | —    | dBm  |
| Error vector magnitude  | EVM    | —    | 8    | 13   | %    |
| Output power control range <sup>3</sup>                                   |        | —    | 40   | —    | dB   |
| Over the air data rate  |        | —    | 250  | _    | kbps |
| 2nd harmonic <sup>4</sup>   |        | —    | <-50 | <-40 | dBm  |
| 3rd harmonic <sup>4</sup>   |        | —    | <-50 | <-40 | dBm  |

<sup>1</sup> [f-fc] > 3.5 MHz, average spectral power is measured in 100 kHz resolution BW.

 $^2$  For the relative limit, the reference level is the highest reference power measured within  $\pm$  1 MHz of the carrier frequency

<sup>3</sup> Measurement is at the package pin on the output of the Tx/Rx switch. It does not degrade more than ±2 dB across temperature and an additional ±1 dB across all processes. Power adjustment will span nominally from –30 dBm to +10 dBm in 21 steps @ 2 dBm / step.

<sup>4</sup> Measured with output power set to nominal (0 dBm) and temperature @ 25°C. If trap filter is needed must meet reference board size requirements.

# 9.2.1 SPI timing: R\_SSEL\_B to R\_SCLK

The following diagram describes timing constraints that must be guaranteed by the system designer.

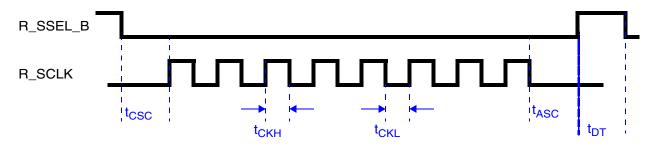


Figure 24. SPI timing: R\_SSEL\_B to R\_SCLK

t<sub>CSC</sub> (CS-to-SCK delay): 31.25 ns

t<sub>ASC</sub> (After SCK delay): 31.25 ns

t<sub>DT</sub> (Minimum CS idle time): 62.5 ns

t<sub>CKH</sub> (Minimum R\_SCLK high time): 31.25 ns (for SPI writes); 55.55 ns (for SPI reads)

t<sub>CKL</sub> (Minimum R\_SCLK low time): 31.25 ns (for SPI writes); 55.55 ns (for SPI reads)

### NOTE

The SPI master device deasserts R\_SSEL\_B only on byte boundaries, and only after guaranteeing the  $t_{ASC}$  constraint shown above.

# 9.2.2 SPI timing: R\_SCLK to R\_MOSI and R\_MISO

The following diagram describes timing constraints that must be guaranteed by the system designer. These constraints apply to the Master SPI (R\_MOSI), and are guaranteed by the radio SPI (R\_MISO).

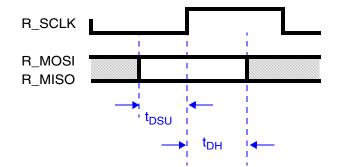


Figure 25. SPI timing: R\_SCLK to R\_MOSI and R\_MISO

t<sub>DSU</sub> (data-to-SCK setup): 10 ns

t<sub>DH</sub> (SCK-to-data hold): 10 ns

| Characteristic  | Symbol | Тур | Unit |
|---|--------|-----|------|
| RFIN Pins for internal T/R switch configuration, TX mode<br>2.360 GHz<br>2.420 GHz<br>2.480 GHz             | Zin    | TBD | Ω    |
| RFIN Pins for internal or external T/R switch configuration, RX mode<br>2.360 GHz<br>2.420 GHz<br>2.480 GHz | Zin    | TBD | Ω    |
| PAO Pins for external T/R switch configuration, TX mode<br>2.360 GHz<br>2.420 GHz<br>2.480 GHz              | Zin    | TBD | Ω    |

 Table 13. RF port impedance

# 10 Crystal oscillator reference frequency

This section provides application specific information regarding crystal oscillator reference design and recommended crystal usage.

# 10.1 Crystal oscillator design considerations

The IEEE ® 802.15.4 Standard requires that frequency tolerance be kept within ±40 ppm accuracy. This means that a total offset up to 80 ppm between transmitter and receiver will still result in acceptable performance. The MKW2xDxxxV transceiver provides on board crystal trim capacitors to assist in meeting this performance, while the bulk of the crystal load capacitance is external.

# 10.2 Crystal requirements

The suggested crystal specification for the MKW2xDxxxV is shown in Table 14. A number of the stated parameters are related to desired package, desired temperature range and use of crystal capacitive load trimming.

| Parameter                           | Value | Unit | Condition                      |
|-------------------------------------|-------|------|--------------------------------|
| Frequency                           | 32    | MHz  |                                |
| Frequency tolerance (cut tolerance) | ±10   | ppm  | at 25°C                        |
| Frequency stability (temperature)   | ±25   | ppm  | Over desired temperature range |
| Aging <sup>1</sup>                  | ±2    | ppm  | max                            |
| Equivalent series resistance        | 60    | Ω    | max                            |
| Load capacitance                    | 5–9   | pF   |                                |
| Shunt capacitance                   | <2    | pF   | max                            |
| Mode of oscillation                 |       |      | fundamental                    |

Table 14. MKW2xDxxxV crystal specifications

<sup>1</sup> A wider aging tolerance may be acceptable if application uses trimming at production final test.

# 11 Pin assignments

| Typical<br>feature | MKW2<br>2/24D5<br>12V<br>(USB) | MKW2<br>1Dxxx<br>V | Pin<br>Name          | Default       | ALT0 | ALT1                 | ALT2          | ALT3         | ALT4         | ALT5 | ALT6         | ALT7 |
|--------------------|--------------------------------|--------------------|----------------------|---------------|------|----------------------|---------------|--------------|--------------|------|--------------|------|
| RADIO              | 1                              | 1                  | EXTAL_<br>32M        | EXTAL_<br>32M | _    | —                    | _             | _            | _            |      | _            | —    |
| RADIO              | 2                              | 2                  | GPIO1                | GPIO1         | —    | —                    | —             | —            | —            | —    | —            | —    |
| RADIO              | 3                              | 3                  | GPIO2                | GPIO2         | —    | —                    | —             | —            | —            | —    | —            | —    |
| SPI0               | 4                              | 4                  | PTC4/<br>LLWU_<br>P8 | DISABL<br>ED  | _    | PTC4/<br>LLWU_<br>P8 | SPI0_P<br>CS0 | UART1<br>_TX | FTM0_<br>CH3 | _    | CMP1_<br>OUT | _    |

| Typical<br>feature      | MKW2<br>2/24D5<br>12V<br>(USB) | MKW2<br>1Dxxx<br>V | Pin<br>Name           | Default        | ALT0           | ALT1                  | ALT2          | ALT3                                    | ALT4                 | ALT5                  | ALT6          | ALT7                   |
|-------------------------|--------------------------------|--------------------|-----------------------|----------------|----------------|-----------------------|---------------|---|----------------------|-----------------------|---------------|------------------------|
| SPI0                    | 5                              | 5                  | PTC5/<br>LLWU_<br>P9  | DISABL<br>ED   | _              | PTC5/<br>LLWU_<br>P9  | SPI0_S<br>CK  | LPTMR<br>0_ALT2                         | 12S0_R<br>XD0        | _                     | CMP0_<br>OUT  | -                      |
| SPI0                    | 6                              | 6                  | PTC6/<br>LLWU_<br>P10 | CMP0_I<br>N0   | CMP0_I<br>N0   | PTC6/<br>LLWU_<br>P10 | SPI0_S<br>OUT | PDB0_<br>EXTRG                          | I2S0_R<br>X_BCL<br>K | -                     | I2S0_M<br>CLK | -                      |
| SPI0                    | 7                              | 7                  | PTC7                  | CMP0_I<br>N1   | CMP0_I<br>N1   | PTC7                  | SPI0_SI<br>N  | USB_S<br>OF_OU<br>T                     | I2S0_R<br>X_FS       | —                     | —             | —                      |
| SPI0                    | 8                              | 8                  | PTD1                  | ADC0_<br>SE5b  | ADC0_<br>SE5b  | PTD1                  | SPI0_S<br>CK  | UART2<br>_CTS_b                         | -                    | -                     | -             | -                      |
| I2C                     | 9                              | 9                  | PTD2/<br>LLWU_<br>P13 | DISABL<br>ED   | _              | PTD2/<br>LLWU_<br>P13 | SPI0_S<br>OUT | UART2<br>_RX                            | I2C0_S<br>CL         | _                     | _             | GPIO4_<br>BSM_D<br>ATA |
| I2C                     | 10                             | 10                 | PTD3                  | DISABL<br>ED   | —              | PTD3                  | SPI0_SI<br>N  | _TX                                     | I2C0_S<br>DA         | —                     | —             | GPIO5_<br>BSM_C<br>LK  |
| UART0                   | 11                             | 11                 | PTD4/<br>LLWU_<br>P14 | mADC0<br>_SE21 | mADC0<br>_SE21 | PTD4/<br>LLWU_<br>P14 | SPI0_P<br>CS1 | UART0<br>_RTS_b                         | FTM0_<br>CH4         | —                     | EWM_I<br>N    | GPIO_B<br>SM_FR<br>AME |
| UART0                   | 12                             | 12                 | PTD5                  | ADC0_<br>SE6b  | ADC0_<br>SE6b  | PTD5                  | SPI0_P<br>CS2 | UART0<br>_CTS_b<br>/<br>UART0<br>_COL_b | FTM0_<br>CH5         | _                     | EWM_O<br>UT_b | _                      |
| UART0                   | 13                             | 13                 | PTD6/<br>LLWU_<br>P15 | ADC0_<br>SE7b  | ADC0_<br>SE7b  | PTD6/<br>LLWU_<br>P15 | SPI0_P<br>CS3 | UART0<br>_RX                            | FTM0_<br>CH6         | -                     | FTM0_F<br>LT0 | -                      |
| UART0                   | 14                             | 14                 | PTD7                  | mADC0<br>_SE22 | mADC0<br>_SE22 | PTD7                  | CMT_IR<br>O   | UART0<br>_TX                            | FTM0_<br>CH7         | —                     | FTM0_F<br>LT1 | —                      |
| TRACE,<br>UART1,<br>I2C | 15                             | 15                 | PTE0                  | mADC0<br>_SE10 | mADC0<br>_SE10 | PTE0                  | SPI1_P<br>CS1 | UART1<br>_TX                            | —                    | mTRAC<br>E_CLK<br>OUT | I2C1_S<br>DA  | RTC_C<br>LKOUT         |
| TRACE,                  | 16                             | 16                 | PTE1/<br>LLWU_<br>P0  | mADC0<br>_SE11 | mADC0<br>_SE11 | PTE1/<br>LLWU_<br>P0  | SPI1_S<br>OUT | UART1<br>_RX                            | _                    | mTRAC<br>E_D3         | I2C1_S<br>CL  | SPI1_SI<br>N           |
| TRACE,                  | 17                             | 17                 | PTE2/<br>LLWU_<br>P1  | mADC0<br>_DP1  | mADC0<br>_DP1  | PTE2/<br>LLWU_<br>P1  | SPI1_S<br>CK  | UART1<br>_CTS_b                         | _                    | mTRAC<br>E_D2         | _             | -                      |
| TRACE,                  | 18                             | 18                 | PTE3                  | mADC0<br>_DM1  | mADC0<br>_DM1  | PTE3                  | SPI1_SI<br>N  | UART1<br>_RTS_b                         | -                    | mTRAC<br>E_D1         | -             | SPI1_S<br>OUT          |
| TRACE,                  | 19                             | 19                 | PTE4/<br>LLWU_<br>P2  | DISABL<br>ED   | -              | PTE4/<br>LLWU_<br>P2  | SPI1_P<br>CS0 | -                                       | -                    | mTRAC<br>E_D0         | -             | —                      |
| —                       | 20                             | 20                 | VDD_M<br>CU           | VDD_M<br>CU    | VDD_M<br>CU    | -                     | -             | -                                       | -                    | -                     | -             | -                      |

| Typical<br>feature    | MKW2<br>2/24D5<br>12V<br>(USB) | MKW2<br>1Dxxx<br>V | Pin<br>Name                          | Default                                       | ALT0                                 | ALT1  | ALT2                                    | ALT3            | ALT4           | ALT5 | ALT6            | ALT7                          |
|-----------------------|--------------------------------|--------------------|--------------------------------------|---|--------------------------------------|-------|---|-----------------|----------------|------|-----------------|-------------------------------|
| —                     | —                              | 21                 | PTE16                                | ADC0_<br>SE4a                                 | ADC0_<br>SE4a                        | PTE16 | SPI0_P<br>CS0                           | UART2<br>_TX    | FTM_C<br>LKIN0 | _    | FTM0_F<br>LT3   | -                             |
| —                     | —                              | 22                 | PTE17                                | ADC0_<br>SE5a                                 | ADC0_<br>SE5a                        | PTE17 | SPI0_S<br>CK                            | UART2<br>_RX    | FTM_C<br>LKIN1 | —    | LPTMR<br>0_ALT3 | —                             |
| _                     | —                              | 23                 | PTE18                                | ADC0_<br>SE6a                                 | ADC0_<br>SE6a                        | PTE18 | SPI0_S<br>OUT                           | UART2<br>_CTS_b | I2C0_S<br>DA   | -    | _               | —                             |
| —                     | —                              | 24                 | PTE19                                | ADC0_<br>SE7a                                 | ADC0_<br>SE7a                        | PTE19 | SPI0_SI<br>N                            | UART2<br>_RTS_b | 12C0_S<br>CL   |      | —               | —                             |
| USB                   | 21                             | -                  | USB0_<br>DP                          | USB0_<br>DP                                   | USB0_<br>DP                          | _     | —                                       | —               | —              | —    | -               | -                             |
| USB                   | 22                             | -                  | USB0_<br>DM                          | USB0_<br>DM                                   | USB0_<br>DM                          | _     | -                                       | -               | -              | _    | -               | -                             |
| USB                   | 23                             | -                  | VOUT3<br>3                           | VOUT3<br>3                                    | VOUT3<br>3                           | _     | -                                       | -               | -              | _    | -               | -                             |
| USB                   | 24                             | -                  | VREGI<br>N                           | VREGI<br>N                                    | VREGI<br>N                           | -     | —                                       | —               | -              | -    | -               | —                             |
| Analog<br>Power       | 25                             | 25                 | VDDA                                 | VDDA  | VDDA                                 | -     | —                                       | —               | -              | _    | -               | —                             |
| Analog<br>Power       | 26                             | 26                 | VREFH                                | VREFH   | VREFH                                | -     | —                                       | —               | -              | _    | -               | —                             |
| Analog<br>Power       | 27                             | 27                 | VREFL                                | VREFL   | VREFL                                | -     | -                                       | —               | -              | _    | -               | —                             |
| Analog<br>Power       | 28                             | 28                 | VSSA                                 | VSSA  | VSSA                                 | -     | -                                       | -               | -              | _    | -               | -                             |
| Tamper                | 29                             | 29                 | TAMPE<br>R0/<br>RTC_W<br>AKEUP<br>_B | TAMPE<br>R0/<br>RTC_W<br>AKEUP<br>_B          | TAMPE<br>R0/<br>RTC_W<br>AKEUP<br>_B | _     | _                                       | _               | _              | _    | -               | _                             |
| VBAT,<br>32KHz<br>OSC | 30                             | 30                 | XTAL32                               | XTAL32  | XTAL32                               | -     | —                                       | _               | -              | -    | -               | -                             |
| VBAT,<br>32KHz<br>OSC | 31                             | 31                 | EXTAL3<br>2                          | EXTAL3<br>2                                   | EXTAL3<br>2                          | _     | —                                       | _               | —              | _    | -               | -                             |
| VBAT,<br>32KHz<br>OSC | 32                             | 32                 | VBAT_<br>MCU                         | VBAT_<br>MCU                                  | VBAT_<br>MCU                         | -     | -                                       | -               | -              | -    | -               | -                             |
| JTAG,<br>Timer        | 33                             | 33                 | PTA0                                 | JTAG_T<br>CLK/<br>SWD_C<br>LK/<br>EZP_CL<br>K | -                                    | PTA0  | UART0<br>_CTS_b<br>/<br>UART0<br>_COL_b | FTM0_<br>CH5    | -              | -    | -               | JTAG_T<br>CLK/<br>SWD_C<br>LK |

| Typical<br>feature | 2/24D5<br>12V<br>(USB) | MKW2<br>1Dxxx<br>V | Pin<br>Name          | Default                                       |             | ALT1                 | ALT2            | ALT3          | ALT4           | ALT5 | ALT6            | ALT7                           |
|--------------------|------------------------|--------------------|----------------------|---|-------------|----------------------|-----------------|---------------|----------------|------|-----------------|--------------------------------|
| JTAG,<br>Timer     | 34                     | 34                 | PTA1                 | JTAG_T<br>DI/<br>EZP_DI                       | _           | PTA1                 | UART0<br>_RX    | FTM0_<br>CH6  | _              | _    | _               | JTAG_T<br>DI                   |
| JTAG,<br>Timer     | 35                     | 35                 | PTA2                 | JTAG_T<br>DO/<br>TRACE<br>_SWO/<br>EZP_D<br>O | _           | PTA2                 | UART0<br>_TX    | FTM0_<br>CH7  | _              | _    | _               | JTAG_T<br>DO/<br>TRACE<br>_SWO |
| JTAG,<br>Timer     | 36                     | 36                 | PTA3                 | JTAG_T<br>MS/<br>SWD_D<br>IO                  |             | PTA3                 | UART0<br>_RTS_b | FTM0_<br>CH0  |                |      | _               | JTAG_T<br>MS/<br>SWD_D<br>IO   |
| NMI                | 37                     | 37                 | PTA4/<br>LLWU_<br>P3 | NMI_b/<br>EZP_C<br>S_b                        | -           | PTA4/<br>LLWU_<br>P3 | -               | FTM0_<br>CH1  |                |      | —               | NMI_b                          |
| -                  | 38                     | 38                 | VDD_M<br>CU          | VDD_M<br>CU                                   | VDD_M<br>CU | -                    | —               | -             | -              | -    | -               | —                              |
| MCU<br>XTAL        | 39                     | 39                 | PTA18                | EXTAL0  | EXTAL0      | PTA18                | -               | FTM0_F<br>LT2 | FTM_C<br>LKIN0 | -    | -               | -                              |
| MCU<br>XTAL        | 40                     | 40                 | PTA19                | XTAL0   | XTAL0       | PTA19                | —               | FTM1_F<br>LT0 | FTM_C<br>LKIN1 | _    | LPTMR<br>0_ALT1 | -                              |
| RESET              | 41                     | 41                 | RESET<br>_b          | RESET<br>_b                                   | RESET<br>_b | -                    | —               | -             | -              | _    | _               | -                              |
| RADIO              | 42                     | 42                 | VBAT2_<br>RF         | VBAT3_<br>RF                                  | -           | —                    | —               | -             | _              | -    | _               | _                              |
| RADIO              | 43                     | 43                 | VDD_R<br>EGD         | VDD_R<br>EGD                                  | -           | —                    | —               | -             | _              | -    | —               | -                              |
| RADIO              | 44                     | 44                 | ANT_A                | ANT_A   | —           | _                    | _               | —             | _              | _    | —               | —                              |
| RADIO              | 45                     | 45                 | ANT_B                | ANT_B   | —           | —                    | —               | —             | —              | _    | —               | —                              |
| RADIO              | 46                     | 46                 | RX_SW<br>ITCH        | RX_SW<br>ITCH                                 | -           | -                    | -               | -             | -              | -    | —               | -                              |
| RADIO              | 47                     | 47                 | TX_SWI<br>TCH        | TX_SWI<br>TCH                                 | -           | _                    | —               | -             | -              | -    | _               | _                              |
| RADIO              | 48                     | 48                 | GND_P<br>A           | GND_P<br>A                                    | -           | -                    | —               | -             | -              | -    | -               | -                              |
| RADIO              | 49                     | 49                 | RF_OU<br>TP          | RF_OU<br>TP                                   | -           | -                    | -               | -             | -              | -    | -               | —                              |
| RADIO              | 50                     | 50                 | RF_OU<br>TN          | RF_OU<br>TN                                   | -           | -                    | —               | -             | -              | -    | -               | -                              |
| RADIO              | 51                     | 51                 | GND_P<br>A           | GND_P<br>A                                    | -           | -                    | —               | -             | -              | -    | -               | —                              |
| RADIO              | 52                     | 52                 | VDD_P<br>A           | VDD_P<br>A                                    | —           | —                    | —               | —             | —              | -    | -               | -                              |

| Typical<br>feature | MKW2<br>2/24D5<br>12V<br>(USB) | MKW2<br>1Dxxx<br>V | Pin<br>Name     | Default                 | ALT0 | ALT1 | ALT2 | ALT3 | ALT4 | ALT5 | ALT6 | ALT7 |
|--------------------|--------------------------------|--------------------|-----------------|-------------------------|------|------|------|------|------|------|------|------|
| RADIO              | 53                             | 53                 | VDD_IF          | VDD_IF                  | -    | —    | —    |      | —    | -    | —    | —    |
| RADIO              | 54                             | 54                 | VDD_R<br>F      | VDD_R<br>F              | -    | -    | -    | -    | -    | -    |      | -    |
| RADIO              | 55                             | 55                 | VBAT_<br>RF     | VBAT_<br>RF             | -    | -    | -    | -    | -    | -    |      | -    |
| RADIO              | 56                             | 56                 | XTAL_3<br>2M    | XTAL_3<br>2M            | -    | -    | -    | -    | -    | -    | -    | -    |
| RADIO              | 57                             | 57                 | Factory<br>Test | Do not<br>connect       | -    | -    | -    | -    | -    | -    | -    | -    |
| RADIO              | 58                             | 58                 | Factory<br>Test | Do not<br>connect       | -    | -    | -    | -    | -    | -    | -    | -    |
| RADIO              | 59                             | 59                 | Factory<br>Test | Do not<br>connect       | -    | -    | -    | -    | -    | -    | -    | -    |
| RADIO              | 60                             | 60                 | Factory<br>Test | Do not<br>connect       | _    | —    | —    | _    | -    | —    | -    | -    |
| RADIO              | 61                             | 61                 | Factory<br>Test | Do not<br>connect       | -    | -    | -    | -    | -    | -    | -    | -    |
| RADIO              | 62                             | 62                 | Factory<br>Test | Do not<br>connect       | -    | —    | —    | -    | —    | —    | -    | -    |
| RADIO              | 63                             | 63                 | GND_P<br>A      | Connect<br>to<br>ground | —    | —    | —    | —    | —    | —    | —    | -    |

# 12 Packaging information

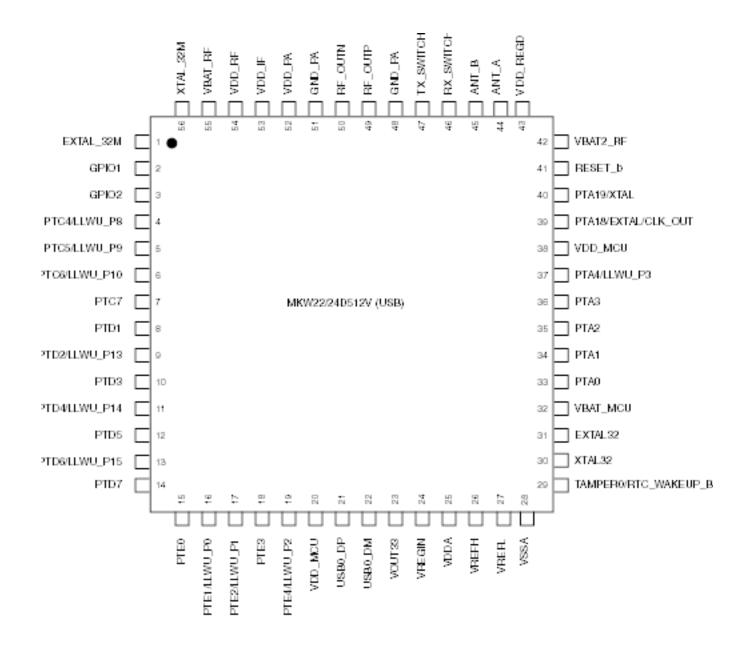


Figure 26. MKW22/24D512V (USB) Pin Assignment

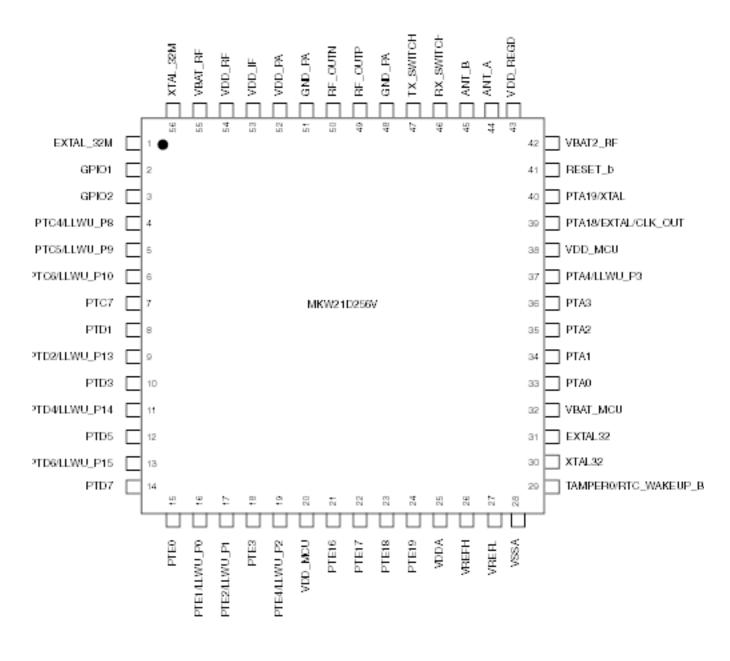
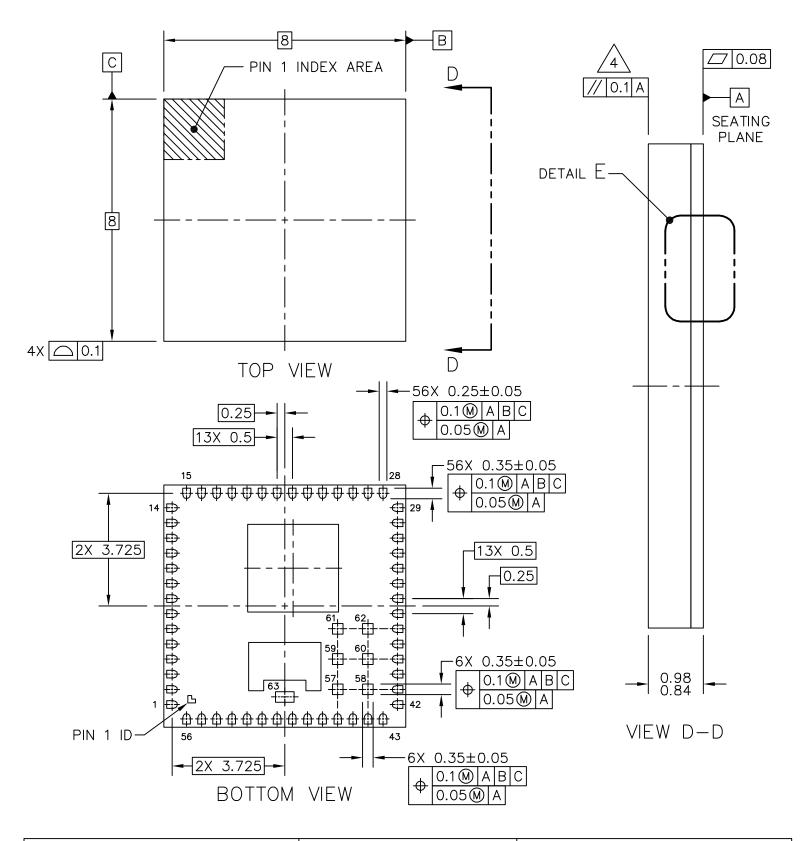
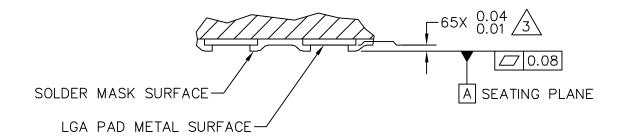


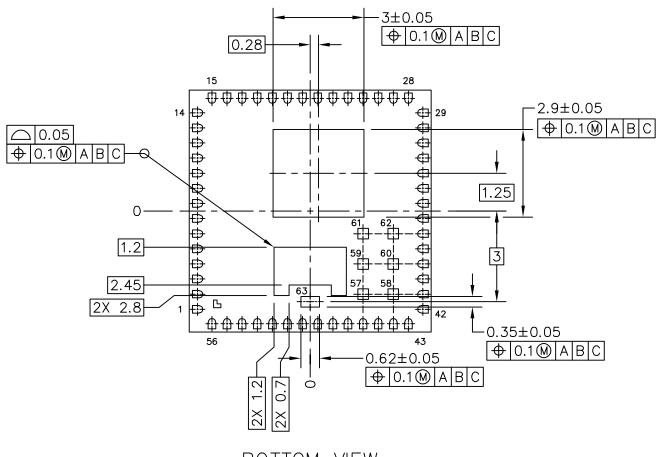
Figure 27. MKW21D256V Pin Assignment



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|---|--|----------------------------|-------------|
|   |  | ENT NO: 98ASA00393D        | REV: A      |
|   |  | IUMBER: 2234-01            | 27 FEB 2012 |
|   |  | STANDARD: NON-JEDEC        |             |



DETAIL E VIEW ROTATED 90' CW



BOTTOM VIEW

| © FREESCALE SEMICONDUCTOR, INC.<br>ALL RIGHTS RESERVED.                   | MECHANICAL OUTLINE |                     | PRINT VERSION NOT TO SCALE |             |
|---|--------------------|---------------------|----------------------------|-------------|
| TITLE: MAPLGA, THIN PROFILE,<br>8 X 8 X 0.91 PKG,<br>0.5 MM PITCH, 63 I/O |                    | DOCUMEN             | NT NO: 98ASA00393D         | REV: A      |
|   |                    | CASE NU             | IMBER: 2234-01             | 27 FEB 2012 |
|   |                    | STANDARD: NON-JEDEC |                            |             |

### NOTES:

′4.

1. ALL DIMENSIONS IN MILLIMETERS.

2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.

3. DIMENSION APPLIES TO ALL LEADS AND FLAG AREAS.

PARALLELISM MEASUREMENT SHALL EXCLUDE ANY EFFECT OF MARK ON TOP SURFACE OF PACKAGE.

| © FREESCALE SEMICONDUCTOR, INC.<br>All RIGHTS RESERVED.                   | MECHANICAL OUTLINE | PRINT VERSION NOT TO SCALE |             |
|---|--------------------|----------------------------|-------------|
| TITLE: MAPLGA, THIN PROFILE,<br>8 X 8 X 0.91 PKG,<br>0.5 MM PITCH, 63 I/O |                    | IENT NO: 98ASA00393D       | REV: A      |
|   |                    | NUMBER: 2234-01            | 27 FEB 2012 |
|   |                    | STANDARD: NON-JEDEC        |             |